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The negative piezoelectric effect of the ferroelectric polymer poly(vinylidene-fluoride)

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Piezoelectricity describes interconversion between electrical charge and mechanical strain. As expected for lattice ions displaced in an electric field, the proportionality constant is positive for all piezoelectric materials. The exception is poly(vinylidene-fluoride) (PVDF), which exhibits a negative longitudinal piezoelectric coefficient. Reported explanations consider exclusively contraction with applied electric field of either the crystalline or the amorphous part of this semi-crystalline polymer. To distinguish between these conflicting interpretations, we have performed in-situ dynamic X-ray diffraction measurements on P(VDF-TrFE) capacitors. We find that the piezoelectric effect is dominated by the change in lattice constant but, surprisingly, it cannot be accounted for by the polarization-biased electrostrictive contribution of the crystalline part alone. Our quantitative analysis shows that an additional contribution is operative, which we argue is due to an electromechanical coupling between the intermixed crystalline lamellae and amorphous regions. Our findings tie the counterintuitive negative piezoelectric response of PVDF and its copolymers to the dynamics of their composite microstructure.

Piezoelectricity describes the conversion of electrical charge to mechanical strain and vice versa. The direct piezoelectric effect is observed as a change in surface charge density of a material in response to an external mechanical stress. The effect is reversible; the thermodynamic equivalent is a change in dimension upon applying an electric field.

A large piezoelectric coefficient, describing the change in spontaneous electrical polarization with applied mechanical stress, is obtained for ferroelectric materials. When an electric field is applied in the direction of the polarization most ferroelectric materials will expand. However, there is one well-known exception. The ferroelectric polymer poly(vinylidene-fluoride) (PVDF) and its copolymers with trifluoroethylene P(VDF-TrFE) show an unusual negative longitudinal piezoelectric effect. Counterintuitively, these polymers contract in the direction of an applied electric field. The two opposite behaviours are schematically represented in Fig. 1.

It has been shown that the strain in PVDF varies with the polarization squared.^[1] Hence the origin of piezoelectricity is electrostriction biased by the spontaneous polarization. A negative piezoelectric coefficient was extracted. Presently, two contradicting microscopic models have been proposed; the piezoelectric response is attributed to either the crystalline or the amorphous part of the semi-crystalline polymer.

Quantum chemical calculations for the ferroelectric β -phase of PVDF have shown that for a single-crystal the piezoelectric effect is negative.^[2] When an electric field is applied perpendicularly to the PVDF chain, the backbone stretches and its height is compressed. The lattice constant is reduced. The calculated coefficient agrees with the value experimentally determined on bulk samples, implying that the change in lattice constant fully accounts for the change in film thickness. This is surprising as PVDF is a semi-crystalline polymer ($\sim 50\%$). Apparently in this analysis the amorphous part was disregarded.

On the other hand, the commonly used explanation for the negative piezoelectric effect of PVDF, the so-called dimensional model, assumes that the dipoles are rigid and retain their fixed moment and orientation during mechanical deformation.^[3,4,5] A detailed description is given in the Supplementary Information (SI;S2). This model basically describes displacement of surface electrodes in the field of fixed PVDF dipole moments.

Piezoelectricity is then due to a change in volume of the amorphous part of the sample. In the dimensional model the crystalline part is disregarded. In summary, according to the current interpretations, the piezoelectric response of PVDF comes either from the crystalline part or from the amorphous part; curiously, each appears to fully account for the experimentally observed piezoelectric response.

The piezoelectric properties of P(VDF-TrFE) have until now been determined macroscopically on films, by measuring the change in film thickness upon application of an electric field. To reveal the microscopic origin of the negative piezoelectric effect, it is not the macroscopic change in film thickness but the change in lattice constant that has to be measured as a function of electric field. However, this requires addressing selectively the contribution of the crystalline part. To that end, we performed *in situ* dynamic X-ray diffraction measurements.

There are severe experimental challenges in performing these X-ray measurements: the minute changes can only be determined *dynamically*, by measuring the diffracted X-ray intensity *in situ*, as a function of a time-varying electric field. Only then can the strain, defined as the relative change in lattice constant, be obtained by statistical averaging over thousands of acquired X-ray diffractograms. Furthermore, the strain is related to the ferroelectric polarization. Hence, to arrive at a quantitative description of the piezoelectric effect in PVDF, the changes in lattice constant have to be measured simultaneously with the ferroelectric polarization, yielding constraints on data acquisition and synchronization. Finally, the diffracted X-ray intensity depends on the atomic structure factors, which for the constituent atoms of PVDF are small. High intensity X-rays from a synchrotron are a prerequisite to obtain a decent signal to noise ratio.

Here we report dynamic in-situ X-ray diffraction measurements on P(VDF-TrFE) capacitors while an electric field is applied. We simultaneously extract the lattice strain and polarization as a function of electric field. The strain is dominated by electrostriction, but an additional contribution has to be included to quantitatively describe the strain for all values of the electric field. This additional contribution can be due to any process that yields a strain that depends linearly on electric field. We argue, based on the microstructure, that the origin is an electromechanical coupling between the intermixed

crystalline lamellae and amorphous regions of the semi-crystalline polymer. Changes in lattice constant upon application of an electric field are coupled to volume changes in the amorphous regions and vice versa. We show that the model developed, unambiguously and quantitatively describes reported strain measurements and we discuss why the piezoelectric coefficient is negative.

The experiment is schematically described in Fig. 2. Details are presented in the SI. Grazing incidence X-ray diffraction (GI-XRD) measurements were performed on P(VDF-TrFE) capacitors. The design of the capacitors was optimized to avoid parasitic diffraction patterns that interfere with the diffraction of P(VDF-TrFE) (SI;S4). An AC voltage was applied over the capacitor and the electric displacement current was measured as a function of time. Crucial for the present experiment is that the X-ray diffractogram is measured as a function of time as well, for which we used a time resolved 2D X-ray detector.^[6,7]

Upon application of an AC voltage on the capacitor, a trigger signal was sent to the X-ray detector starting an exposure-series of ten thousands of images. The specular scattering images recorded were azimuthally integrated and exposures pertaining to the same time-bin relative to the driving frequency were averaged. An example of the signal after integration and binning is presented in Fig. 3a. A clear modulation of the Bragg peak is observed. The wave vector at about 1.3 \AA^{-1} , shown in Fig.3b, is characteristic for the combined (110)/(200) diffraction of the monoclinic low temperature phase of P(VDF-TrFE) (SI;S4). Both the (110) and (200) reflections are perpendicular to the polymer chain direction and thus sensitive to structural dynamics in the transverse-chain direction of the crystals. The electrical data collected from the oscilloscope are shown in Fig. 3c. The driving field (green) and polarization (blue) yield the ferroelectric hysteresis loop. The trigger pulse (red) and the TTL signal from the detector that mirrors the exposures (gray), allow synchronization of the X-ray data (dots) with the electrical measurements. The out of plane lattice constant, the b-axis, which is directed along the sample surface normal and the electric field, is presented as a function of applied AC voltage in Fig.3d. The modulation of the lattice constant is about 0.5 %.

The electric displacement as a function of electric field is presented in Fig. 4a. The strain calculated as the relative change in lattice constant, $\Delta l/l_0$, where l_0 is the value at zero

electric field, is presented in Fig. 4b. The strain, normalized to zero at zero electric field, depends on the relative orientation of electric field and polarization. For clarity the corresponding parts in the displacement vs. field (D - E) and strain vs. field (S - E) loops are presented with identical colours. Looking at Fig. 4b, we start at zero bias with a negatively poled film and increase the electric field (yellow data points). The film expands. The expansion continues until the coercive field, where the polarization switches direction (transition from yellow to red data points). Then the polarization and electric field are aligned in the same direction and the film rapidly contracts (red data points). As a final result, the strain as a function of electric field shows a typical butterfly shape. The strain measurement shows the negative longitudinal piezoelectric effect; the unit cell contracts when an electric field is applied in the direction of the polarization.

To understand the origin of the negative piezoelectric effect the strain measurements have to be quantitatively interpreted. The change in lattice constant can be due to elastic-, Maxwell- and/or piezoelectric strain. The elastic strain describes the deformation of a sample under applied mechanical stress. This direct stress-strain contribution can be disregarded, as external mechanical stress is not applied. Internal mechanical stress, however, can be relevant in the sample through electromechanical coupling, as will be discussed later. The compressive Maxwell strain is due to the electrostatic Coulomb attractive force between opposite charged faces of a dielectric. However, in ferroelectric capacitors the surface charge density is compensated by countercharges of either polarity in the corresponding adjacent electrode.^[8] Hence the Maxwell strain can be disregarded as well. In the Supplementary Information (SI;S8) we show that clamping can be ignored.

The piezoelectric strain in a ferroelectric single-crystal with centrosymmetric paraelectric phase is typically obtained from a free energy expansion in a Taylor series^[9] with respect to either electric displacement, D , or polarization, P . Here we take D as the fundamental variable.^[10] Odd terms in the expansion vanish by symmetry.^[11] The electric displacement is the sum of the induced, P_i , and spontaneous, P_s , polarization, both of which are a function of electric field:

$$D = P_i + P_s = \epsilon_r \epsilon_0 E \dot{p} + P_s \quad (1)$$

where ε_r and ε_0 are the relative and vacuum permittivity. \dot{p} is a parity function, with values of -1 or +1, to account for the relative orientation of electric field and spontaneous polarization, which are independent for a poled piezoelectric material (SI;S9.2). The first non-vanishing term of the Taylor series expansion of the strain, S_{33} , further abbreviated as S , then reads:

$$S_{33} = Q_{33}D^2 = Q_{33}(\varepsilon_r\varepsilon_0E\dot{p} + P_s)^2 = 2Q_{33}\varepsilon_r\varepsilon_0P_sE\dot{p} + Q_{33}P_s^2 + Q_{33}\varepsilon_r^2\varepsilon_0^2E^2 \quad (2)$$

where we have used that \dot{p}^2 equals unity. Q_{33} is the coefficient of electrostriction, a universal property of solid and liquid dielectrics.^[12,13] It is a fourth rank tensor, commonly written with two indices following Voigt's notation. The first term on the right hand side of Eq. [2] corresponds to the piezoelectric effect, with the piezoelectric coefficient equal to $2Q_{33}\varepsilon_r\varepsilon_0P_s$. The piezoelectric effect can thus be understood as the electrostriction biased by the spontaneous polarization. The second term describes the spontaneous strain. The last term, $Q_{33}\varepsilon_r^2\varepsilon_0^2E^2$, is referred to as the pure electrostrictive contribution. For ferroelectric materials this term is small and typically disregarded. We note that Eq. [2] has been widely used to fit the strain as measured interferometrically on uniaxially drawn PVDF films.^[11] However, only data far from the coercive field could be described. The hysteresis and the strain value at zero displacement could not be accounted for. Below we show that for the analysis of our lattice strain measurements an additional contribution to the strain has to be included. In the Supplementary Information (SI;S11) we show that the full reported data set, including the hysteresis, can then unambiguously and quantitatively be described.

From the independent measurements of Fig. 4. a,b, we can directly plot the strain as a function of electric displacement, by elimination of the electric field. We note that although both strain and electric displacement have hysteresis when presented as a function of electric field, the strain as a function of displacement is a hysteresis-free parabola, as predicted by Eq. [2] for a single crystal and as indicated by the dotted line in Fig. 4c.

Similarly, the strain as a function of the displacement squared should be a straight line, as indicated in Fig. 4d. The experimental data of Fig. 4c,d however, do show hysteresis.

The strain is derived from the change in lattice constant of the P(VDF-TrFE) crystals. Surprisingly, however, the strain in P(VDF-TrFE) cannot be described by the single-crystal formalism, Eq. [2].^[11] The hysteresis in lattice strain implies that there must be an additional contribution to the piezoelectric effect. To model the strain, we therefore include an extra term, $d_{coupling} E \dot{p}$, where $d_{coupling}$ is a phenomenological fit constant and E is the applied electric field. \dot{p} is again the parity function, which takes into account that the sign of the strain depends on the relative orientation of electric field and polarization. Such an extra term, which adds to the lattice strain, can be found in the description of piezoelectric response in inorganic polycrystalline materials. In piezoelectric ceramics it has been shown that the strain originating from piezoelectrically induced mechanical interactions among crystallites superimposes linearly to the lattice strain.^[14] We adopt this additive approach, noting that in PVDF and its copolymers the crystallites are intertwined with the soft, non-piezoelectric matrix; intergranular strain is not immediately expected. The microscopic origin of this additional contribution to the strain will be discussed in detail below. Using this approach, the hysteresis can be quantitatively explained. The lattice strain now reads:

$$S_{33} = d_{coupling} E \dot{p} + Q_{33} D^2 = (d_{coupling} + 2Q_{33} \epsilon_r \epsilon_0 P_s) E \dot{p} + Q_{33} P_s^2 + Q_{33} \epsilon_r^2 \epsilon_0^2 E^2 \quad (3)$$

and the linear piezoelectric coefficient, d_{33} , extracted at low electric fields, where the spontaneous polarization can be considered constant and equal to the remanent polarization, is given by:

$$d_{33} = \left. \frac{dS_{33}}{d(\dot{p}E)} \right|_{E=0} = d_{coupling} + 2Q_{33} \epsilon_r \epsilon_0 P_r \quad (4)$$

Extraction of piezoelectric- and electrostrictive coefficients from the strain data of Fig. 4 starts with a quantitative description of polarization as a function of electric field. To that end we use an empirical model^[15,16] that has been previously used to quantitatively

describe ferroelectric capacitors.^[17] The details are presented in the Supplementary Information (SI;S9.1). There are only three empirical parameters, *i.e.* remanent polarization, saturation polarization and coercive field. The fully drawn curve in Fig. 4a is a fit to the experimental displacement *vs.* field data. Once the D - E relation is known, we can simultaneously fit the strain *vs.* field (S - E) and strain *vs.* displacement (S - D , S - D^2) characteristics (Eq.[3]). The fits are presented by the solid lines in Fig. 4b-d. A good agreement is obtained. The fit constants are presented in Table 1. The extracted coupling contribution to the piezoelectric coefficient, $d_{coupling}$, is -20 pm/V and the extracted piezoelectric contribution, $2\epsilon_0\epsilon_r Q_{33}P_s$, is -11 pm/V. The extracted total value of d_{33} is then -31 pm/V. We have extracted the same value from dynamic *in-situ* XRD measurements at low electric field (SI;S10.3). We performed the same analysis on reported strain measurements of ferroelectric β -PVDF films (SI;S11).^[1] We show that the strain can quantitatively be interpreted, for all values of the applied electric field, including hysteresis. The extracted parameters, presented in Table 1, are comparable to those of the copolymer.

Table 1 shows that the *total* value extracted for d_{33} , of about -30 pm/V, is comparable to values derived from strain measurements of bulk samples using, *e.g.* interferometry.^[1,18] This implies that macroscopic piezoelectricity is dominated by the change in lattice constant. This conclusion is surprising. Piezoelectricity in polycrystalline inorganic ferroelectrics is dominated by extrinsic contributions such as domain wall motion.^[19,20] The present analysis shows that for P(VDF-TrFE) the contribution from the change in lattice constant is dominant.

To illustrate that the strain is dominated by electrostriction we present in Fig. 4e,f the experimental strain and the contributions of the electrostrictive and coupling terms, as a function of electric field and electric displacement, respectively. The experimental strain is replotted from Fig. 4b,c. The electrostrictive contribution, presented as the solid lines, is taken as $Q_{33}D^2$. The dotted lines indicate the contribution of the coupling term, $d_{coupling}E\dot{p}$. The strain is clearly dominated by electrostriction. The additional term, $d_{coupling}E\dot{p}$, becomes increasingly important with increasing electric field and introduces the experimentally observed hysteresis.

The electrostrictive coefficient, Q_{33} , is expected to be negative due to the different force constants for the intra- and interchain interactions.^[21] Application of a positive stress perpendicular to the chains mainly increases the distance between the chains, due to the relatively weak van der Waals and electrostatic interactions between the chains, as compared to the strong covalent bonds within the chains. The thickness increase thus results in a decrease of the dipole density, which causes a concomitant decrease of the compensating charges on the electrodes. Consequently the electrostrictive coefficient, Q_{33} , is negative. The piezoelectric coefficient then is also negative, as for a single crystal, d_{33} , is equal to $2\epsilon_r\epsilon_0Q_{33}P_r$. This dipole-induced piezoelectricity^[21] mechanism is confirmed by quantum mechanical calculations for single crystalline polymers.^[2]

We have shown that in order to quantitatively describe the strain as a function of electric field, the additional term $d_{coupling}E\dot{p}$ has to be included. This term can be due to any process that yields a strain that depends linearly on electric field and changes direction at the coercive field. The mechanism could be for instance internal Maxwell stress, interface polarization,^[22] dielectric and/or piezoelectric Maxwell-Wagner relaxations^[23,24] and piezoelectrically-induced mechanical interactions.^[14] We tentatively propose that this additional contribution originates from the composite structure of the polymer, *i.e.* the coexistence of the crystalline and amorphous phase. As shown in the Supplementary Information (SI;S5) the microstructure of PVDF films consists of huge lamellae, sheets of crystals that grow outward starting from a central nucleation site. In between the lamellae is the amorphous phase. The copolymer P(VDF-TrFE) crystallizes in needle-like domains. Details of the packing and folding of the polymer chains are not completely known, but as in PVDF the amorphous and crystalline phases appear to be intermixed.

In a simplified microscopic representation, we consider the film as consisting of alternating crystalline and amorphous slabs. The polarization is due to the dipoles of the crystalline lamellae. The amorphous slab is a linear dielectric. We consider a comprising capacitor. The electric field of the polar lamellae induces a surface charge $\pm Q$ at the top and bottom electrodes. For the sake of explanation, we consider the thermodynamically equivalent direct piezoelectric effect. Assume a compressive stress is applied that decreases the thickness. Part of the deformation is accommodated by contraction of the amorphous

matrix. The concomitant increase of the capacitance dictates that the charges on the electrodes are adjusted by $\pm\Delta Q$. Temporarily there is current flowing through the circuit. The additional charge corresponds to an electric field in the direction of the polarization. The contraction in tandem with the relative orientation of the polarization and the electric field correspond to a negative piezoelectric coefficient, reflected in the additional $d_{coupling}$ term. Because the amorphous parts and the lamellae are not independent but strongly intertwined, this contraction can be regarded as an internal compressive stress to the lamellae, leading to a further reduction of the lattice constant.

Hence in summary, when an electric field is applied over PVDF or its copolymers, the crystalline lamellae contract due to electrostriction, the dipole-induced piezoelectricity. The lattice constant decreases. However, in addition, the amorphous parts in between the polar lamellae contract. This contraction can be regarded as an additional, internal compressive stress to the lamellae, leading to a further reduction of the lattice constant. In first order approximation this additional strain will increase with electric field and therefore can be described by an additional term, $d_{coupling}E\dot{p}$, where the proportionality constant is negative. The piezoelectric coefficient, d_{33} , is negative as both comprising coefficients, $d_{coupling}$ and Q_{33} , are negative.

To support the analysis, we show that the effect depends on the microstructure of the polymer. For this purpose we fabricated capacitors of thick P(VDF-TrFE) films and varied the annealing temperature to control the crystallinity. The microstructure was investigated with DSC and XRD measurements. We measured the strain simultaneously with the displacement as a function of electric field and we modeled the strain according to Eq. [3]. All measurements could be quantitatively interpreted. The data are presented in the Supplementary Information (SI;S12). The extracted electrostrictive coefficient, Q_{33} , can be linked to the Young's modulus and the piezoelectric coefficients, $d_{coupling}$ and d_{33} , vary with the remanent polarization.

In summary, we have performed in-situ dynamic X-ray diffraction measurements on P(VDF-TrFE) capacitors. The strain, as derived from the change in lattice constant with electric field, is comparable to reported strain measured interferometrically on bulk samples. Hence, the piezoelectric effect is dominated by the change in lattice constant but,

surprisingly, it cannot be accounted for by the electrostrictive response of the crystalline part alone. An additional contribution, $d_{coupling} E$, has to be included to quantitatively describe the strain for all values of the electric field. We argue that its origin is the electromechanical coupling between the intermixed crystalline lamellae and amorphous regions of the semi-crystalline polymers. The piezoelectric coefficient, d_{33} , is negative as both comprising coefficients, the electrostrictive, Q_{33} , as well as the additional, $d_{coupling}$, are negative. Our findings tie the negative piezoelectric response of PVDF and its copolymers to the dynamics of their composite microstructure.

Methods

Dynamic in-situ grazing incidence X-ray diffraction measurements (GI-XRD) were performed on P(VDF-TrFE) (65–35%) capacitors as schematically depicted in Fig. 2. Details of the fabrication are presented in the Supplementary Information (SI;S3). To prevent parasitic diffraction patterns we used single crystalline quartz as a substrate, Pd as a bottom electrode and PEDOT:PSS, a water-based suspension of poly(3,4-ethylenedioxythiophene) stabilized with poly(4-styrenesulphonic acid), as a non-diffracting top electrode.

In-situ grazing incidence X-ray diffraction measurements (GI-XRD) were conducted at the High Resolution Diffraction Beamline P08 at PETRAIII, Deutsches Elektron Synchrotron (DESY), Hamburg. A section near the specular plane of the out-of-plane scattering, from the coinciding (200) and (110) Bragg peaks of the aligned sample, was recorded on a time-gated Pilatus 100K area pixel detector, read-out at ~100Hz. We have previously used similar gating techniques to obtain time resolutions below ~100 ps.^[6,7] The scattering vector was measured while displacement loops versus electric field of the samples were recorded using a Sawyer-Tower circuit. For each measurement, 10000 scattering images were recorded, with an integration time of a few milliseconds per image. Details of the dynamic *in-situ* X-ray measurements and the data acquisition procedure are presented in the Supplementary Information (SI;S6). By synchronizing the recording of the

X-ray images to the driving electric field, the scattering could be measured as a function of the instantaneously applied bias.

A triangular waveform was used to drive the ferroelectric capacitors. The applied AC voltage and the capacitor response were recorded as a function of time using the oscilloscope of the Sawyer-Tower system. The X-ray detector started recording after a trigger signal at the zero crossing (rising edge) of the applied bias. The trigger pulse, as well as a TTL signal mirroring the Pilatus exposures, was also recorded by the oscilloscope of the Sawyer-Tower setup. The Bragg peak position was extracted from the X-ray data and synchronized with the electrical data using the oscilloscope traces. Subsequently, the capacitor response (displacement current), the driving signal (applied electric field) and the Bragg peak position (strain) were interpolated and averaged according to a single cycle of the driving signal. Details of the data synchronization procedure are presented in the Supplementary Information (SI;S7).

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Additional information

Author contributions

D.M.d.L. and M.M.N. conceived the idea and designed the experiments. M.L., K.A., D.Z., T.L. and I.K. fabricated and characterized the ferroelectric capacitors. T.B.v.D., K.S.K. and Y.G. performed the synchrotron measurements. I.K. modelled the data. D.D. supervised the theoretical analysis. I.K., K.A., M.L., T.B.v.D., K.S.K., Y.G., P.W.M.B., D.D., M.M.N. and D.M.d.L. co-wrote and commented on the manuscript. I.K. and D.M.d.L. supervised the project.

Competing financial interests: The authors declare no competing financial interests.

Figure 1. Piezoelectricity. Schematic illustration of strain upon application of an electric field in a poled ferroelectric material. (a) The initial state. (b) An electric field is applied in the direction of the polarization in a material with a positive piezoelectric coefficient, such as lead zirconate titanate (PZT). The material expands. (c) The counterintuitive behaviour of PVDF and its copolymers. These materials contract, exhibiting a negative piezoelectric coefficient. The crystal structures are schematically presented.

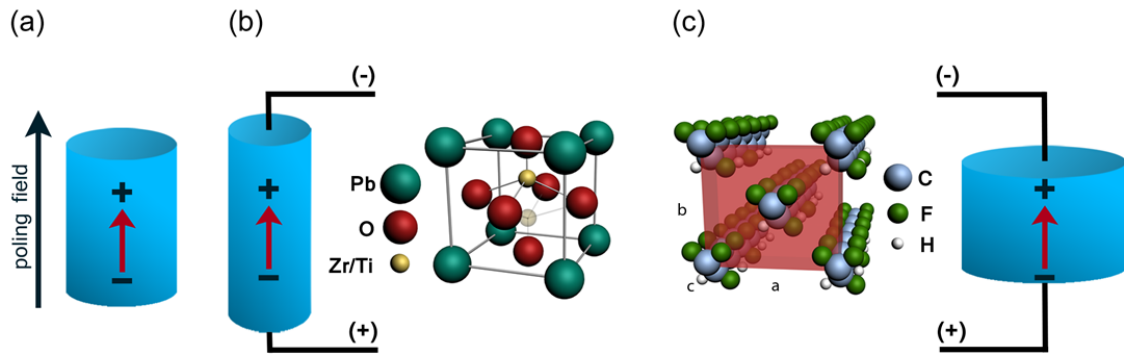


Figure 2. Dynamic in-situ XRD measurement. (a,b) An AC voltage is applied over a P(VDF-TrFE) capacitor. The drive signal and the electric displacement of the ferroelectric capacitor are measured as a function of time and recorded using a Sawyer-Tower set up. (c,d) Upon application of the AC signal on the capacitor, a trigger signal is sent to the X-ray detector starting an exposure-series of ten thousands of images. The 2D X-ray diffraction pattern is measured under grazing incidence synchrotron X-ray irradiation, to enhance the signal to noise ratio. The trigger and detector timing data are recorded by the oscilloscope and all data are transferred to a computer.

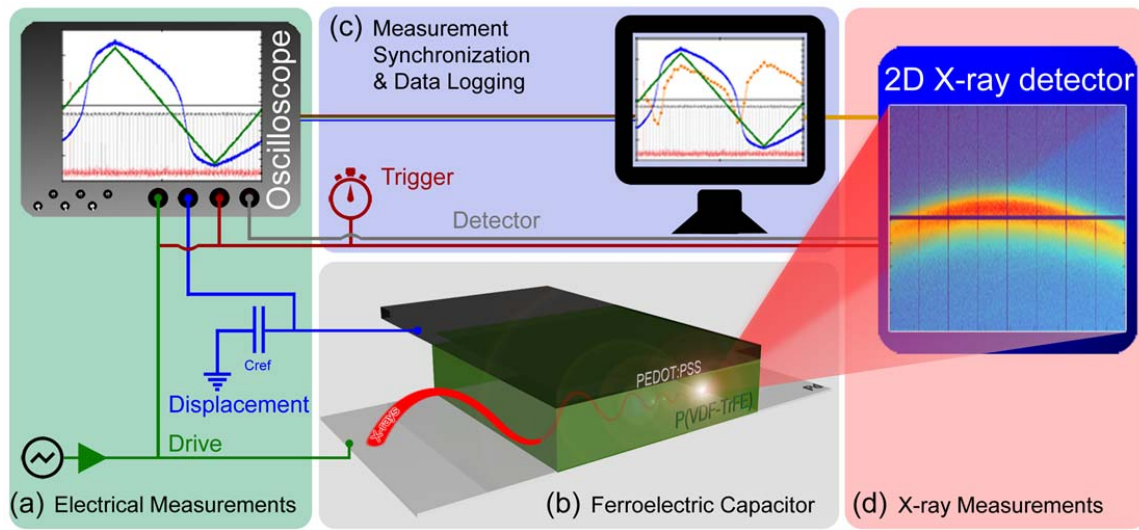


Figure 3. Data acquisition. (a) An example of a processed X-ray signal, showing the scattering vector, Q , as a function of time. Specular scattering images recorded were azimuthally integrated and exposures pertaining to the same time-bin were averaged. The capacitor was driven with a 1 Hz triangular waveform. A clear oscillation of the Bragg peak position is observed. (b) The extracted (110)/(200) diffraction peak of the monoclinic low temperature phase of P(VDF-TrFE). The red line is a single Split Pearson VII fit to the Bragg peak. (c) Recorded data from the oscilloscope, showing the 1 Hz drive signal (green) and the displacement current of the ferroelectric capacitor (blue). The trigger signal (red) starts the series of 10000 X-ray exposures at e.g. 100 Hz, mirrored by the gray lines. The synchronized diffraction data are presented in orange. (d) Lattice constant, derived from the scattering vector Q , as a function of applied AC voltage, following from the synchronized data of (c). Arrows indicate the sweep direction.

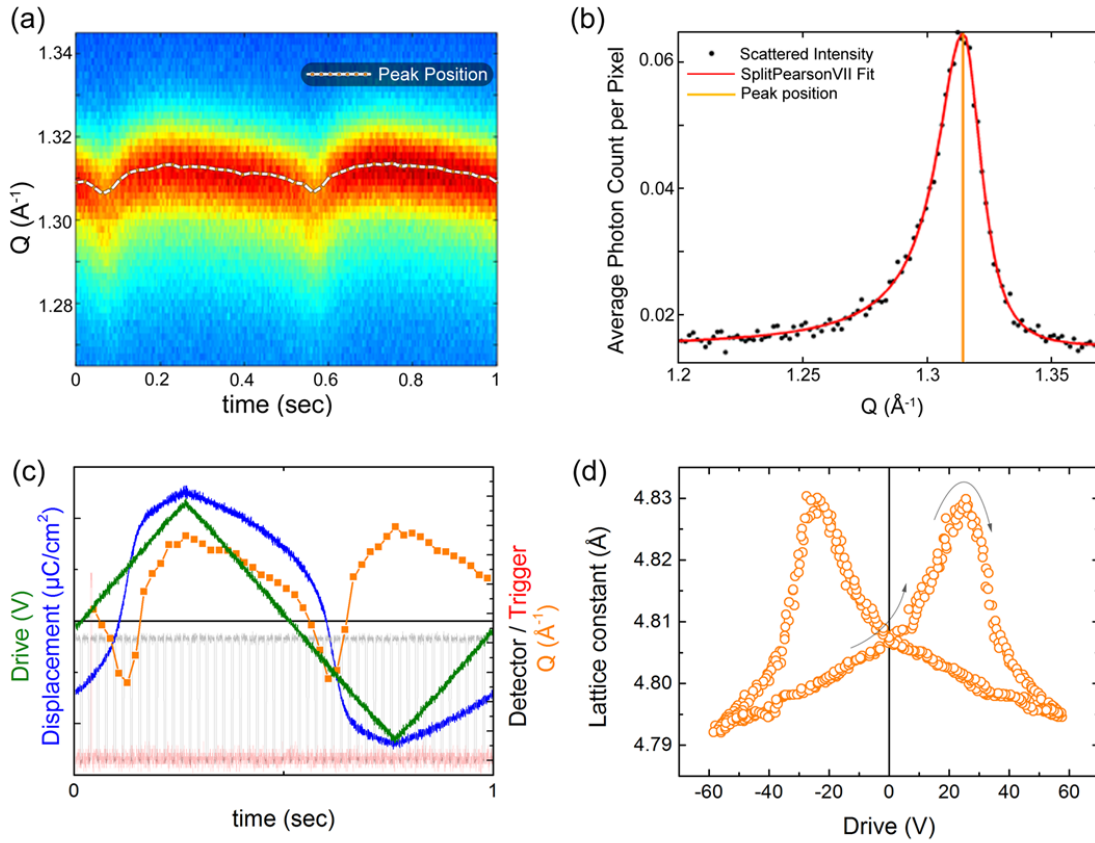


Figure 4. Strain and displacement characteristics of P(VDF-TrFE). (a) Ferroelectric displacement as a function of applied electric field (D - E). The fully drawn curve is a fit according to the empirical model presented in the Supplementary Information (SI;S8.1). Here the capacitor was driven with a 1 Hz triangular waveform. (b,c) Strain as a function of field and displacement (S - E , S - D). (d) Strain as a function of displacement squared (S - D^2). The data have been colour-coded to facilitate the correspondence between the different representations. The dotted lines are the fits according to Eq.[3]. The black fully drawn lines are a fit according to Eq.[4]. The fit constants are presented in Table 1.(e,f) The experimental strain and the contributions of the electrostrictive term, $Q_{33}D^2$ (solid lines), and the coupling term, $d_{\text{coupling}}E\dot{p}$ (dotted lines), as a function of electric field and electric displacement. The strain is clearly dominated by electrostriction. The additional term, $d_{\text{coupling}}E\dot{p}$, becomes increasingly important with increasing electric field and introduces the experimentally observed hysteresis.

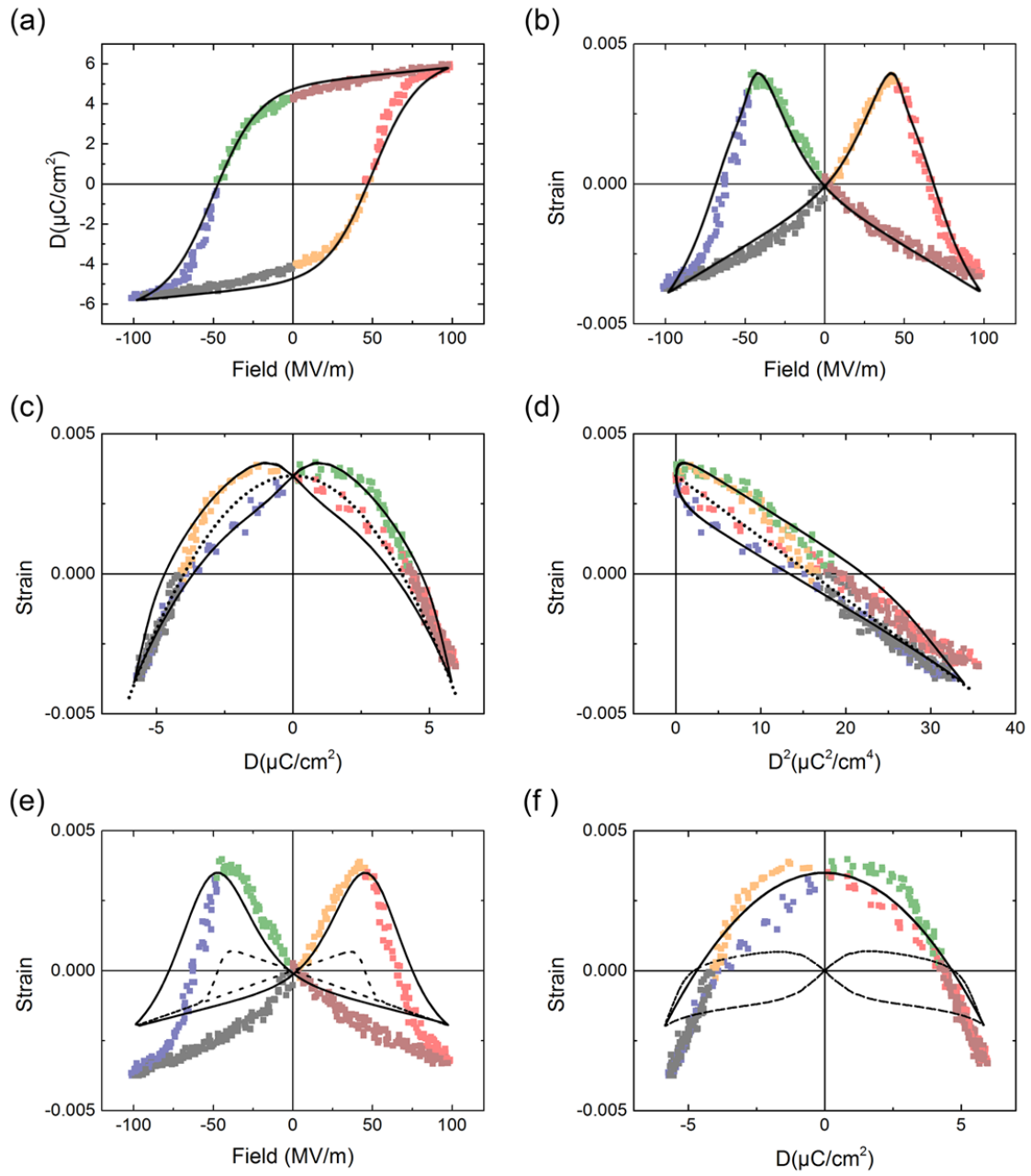


Table 1. Extracted piezoelectric coefficients. *Values in the top row are extracted from modeling the present dynamic in-situ X-ray measurements on P(VDF-TrFE), as shown in Fig.4. Values in the bottom row are extracted from modeling reported strain measurements on bulk films of β -PVDF.^[1] The relative error of the fit parameters, as calculated from an unweighted linear regression analysis, is less than 0.5% for E_c and P_r , less than 4% for $d_{coupling}$ and less than 2% for Q_{33} . The relative error of the total d_{33} , calculated by the propagation of uncertainty, is less than 3%.*

Material	E_c (MV/m)	P_r ($\mu\text{C}/\text{cm}^2$)	Q_{33} (m^4/C^2)	$d_{coupling}$ (pm/V)	$2Q_{33}\epsilon_0\epsilon_rP_r$ (pm/V)	d_{33} (pm/V)
P(VDF-TrFE)	55	4.3	-1.5	-20	-11.4	-31.4
β -PVDF	58	5.5	-1.3	-25	-12.7	-37.7

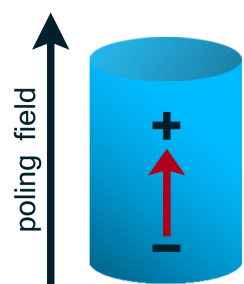
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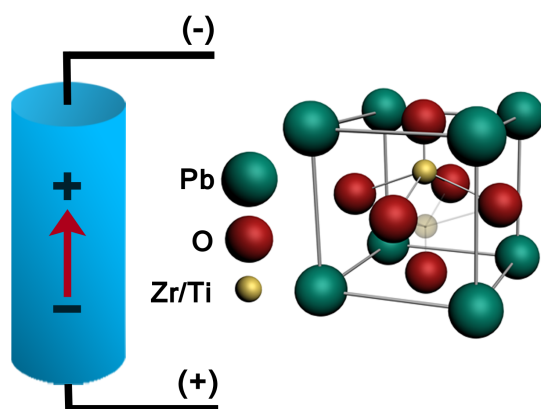
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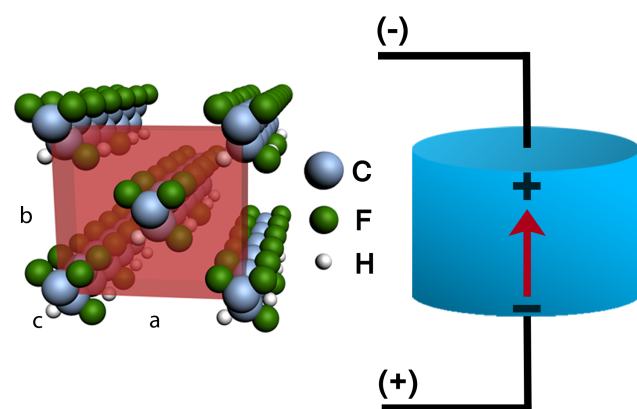
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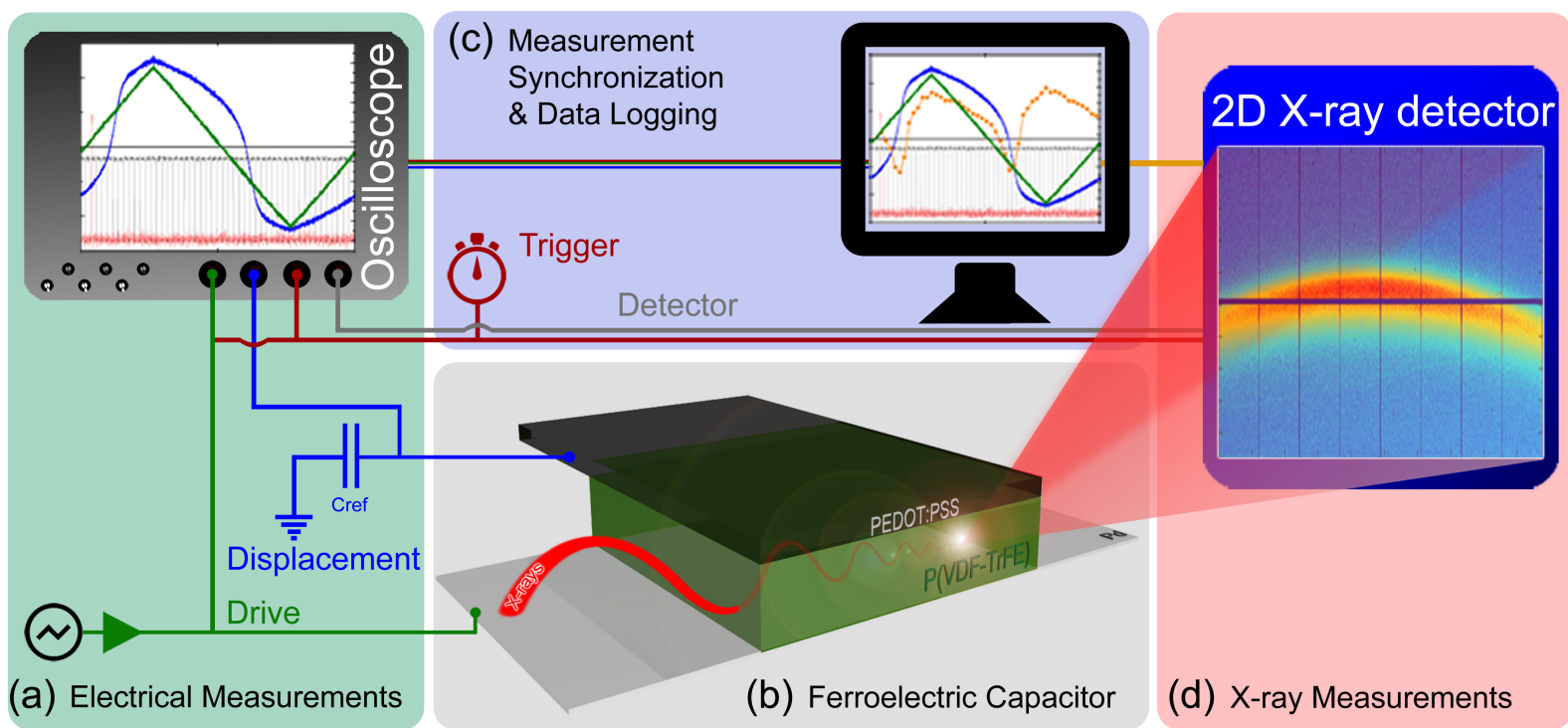


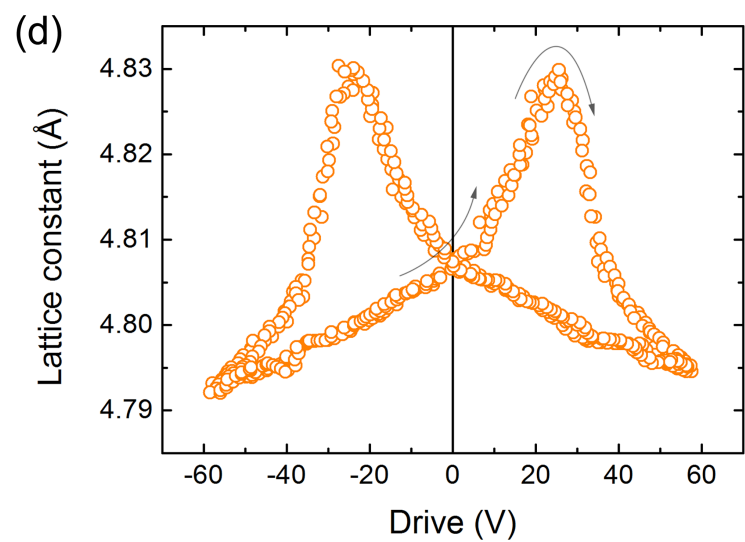
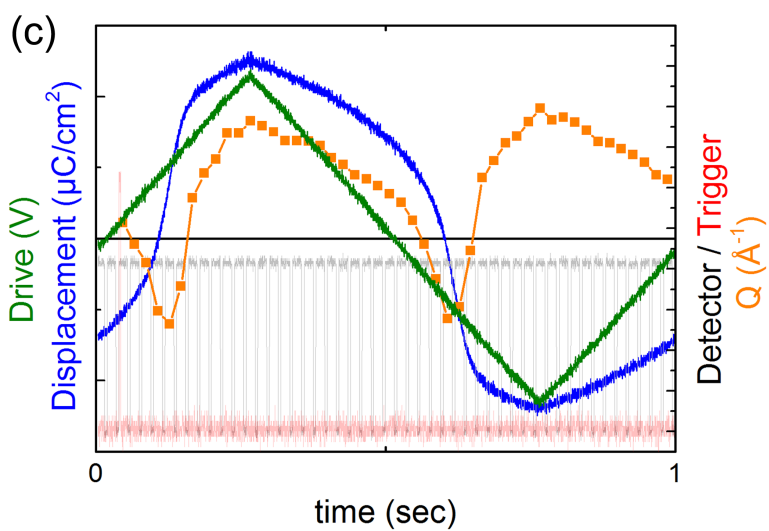
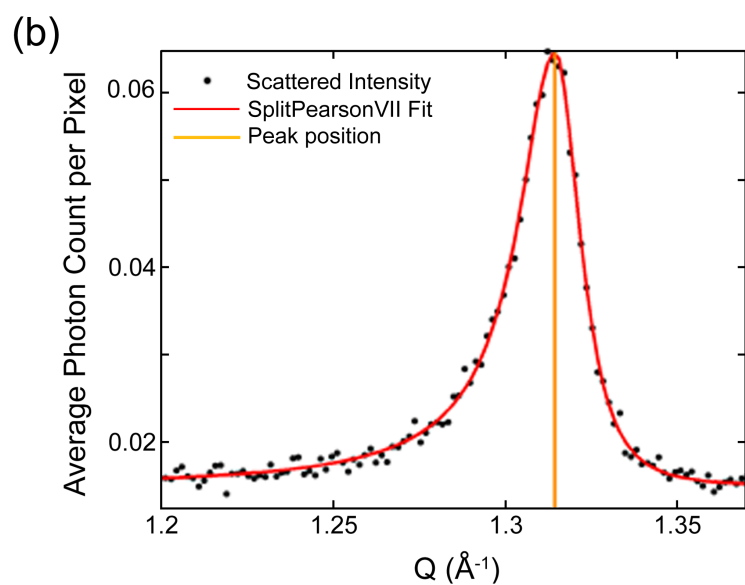
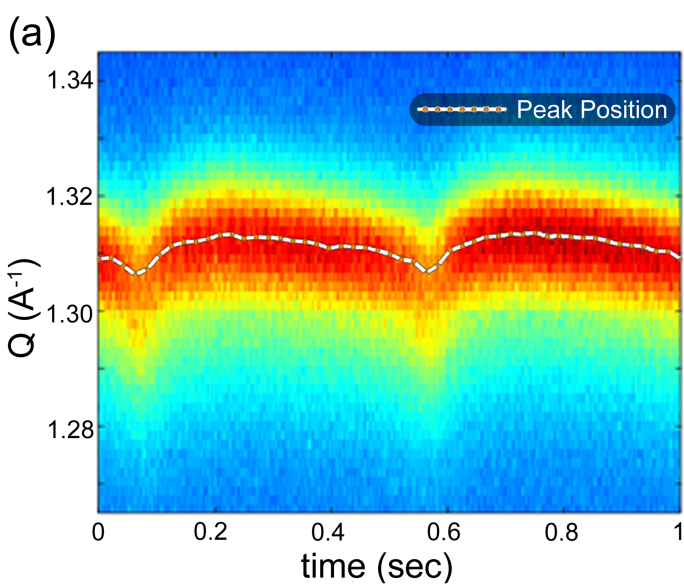
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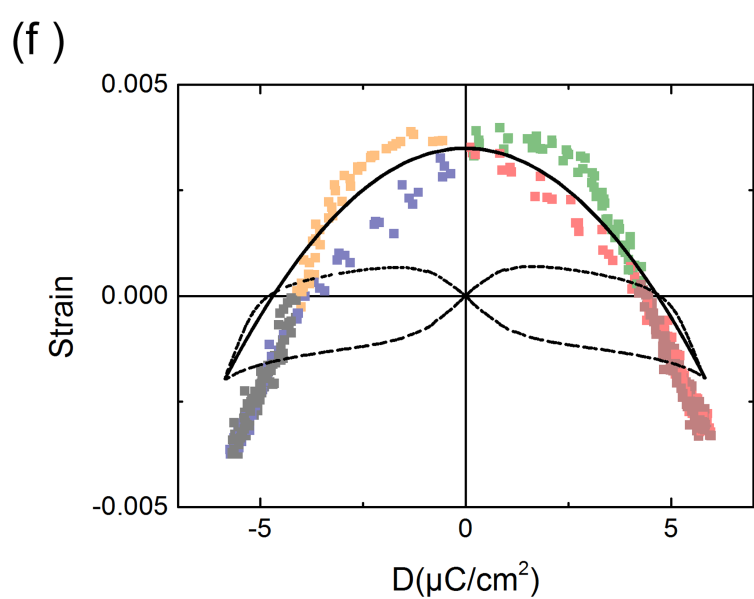
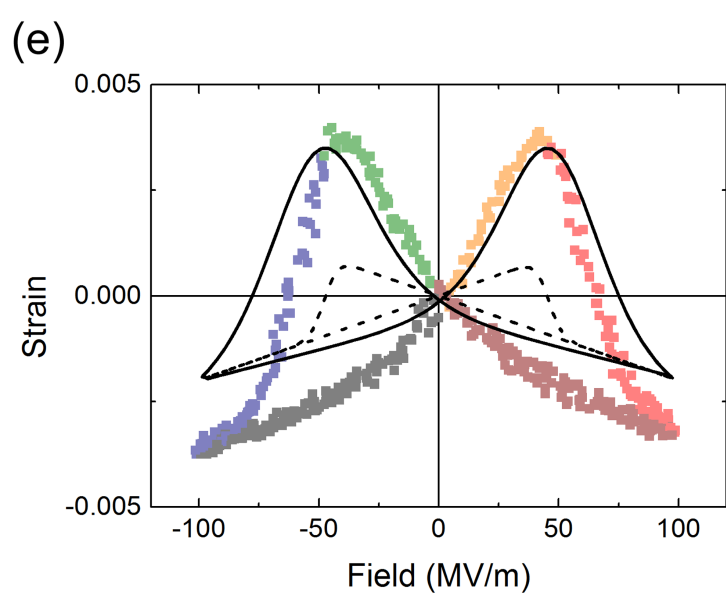
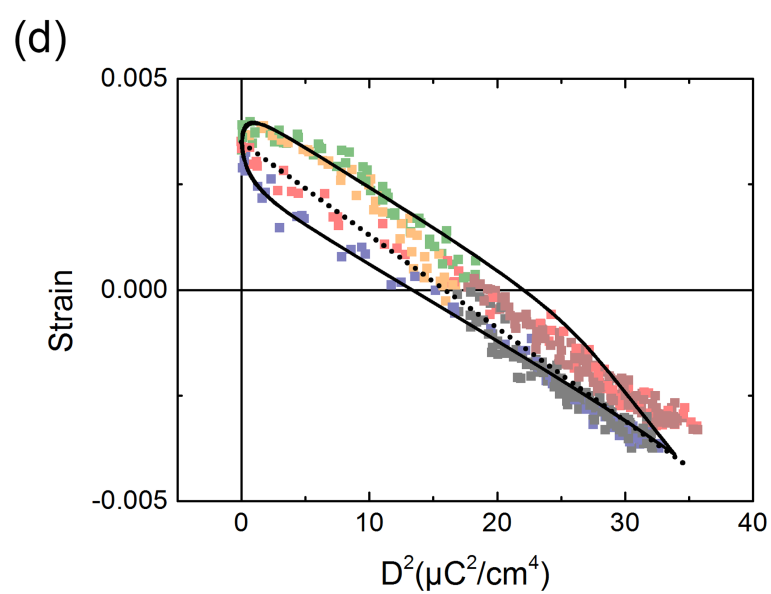
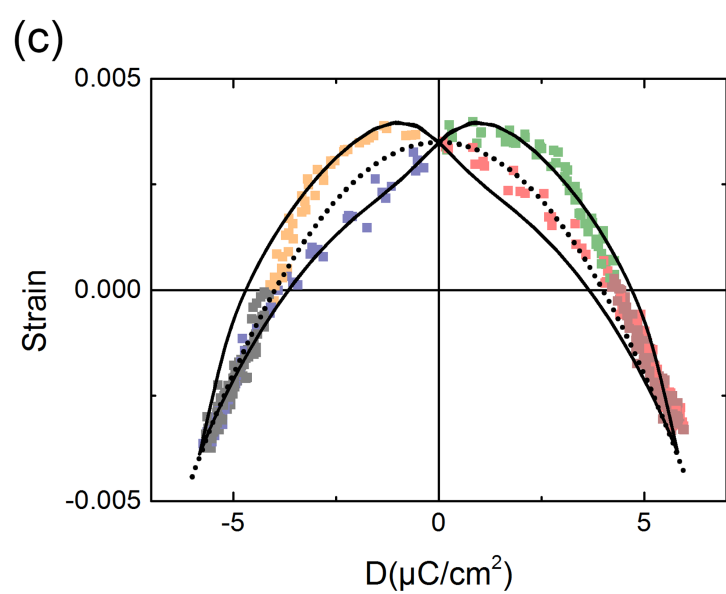
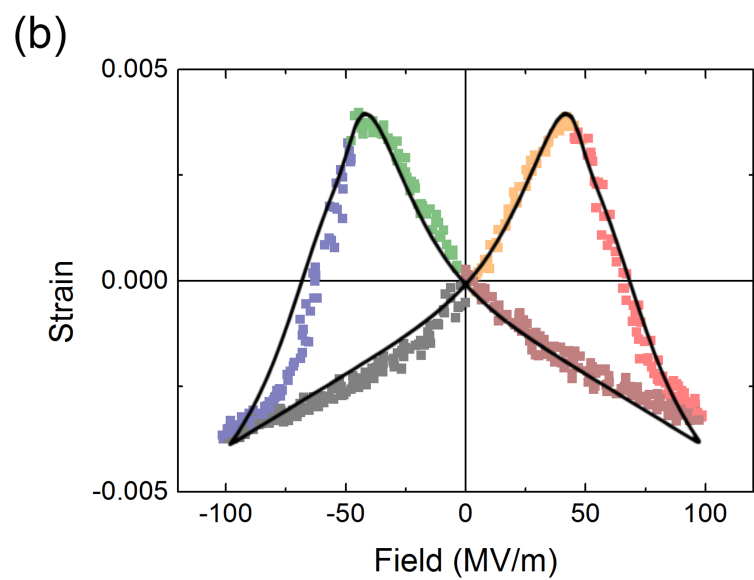
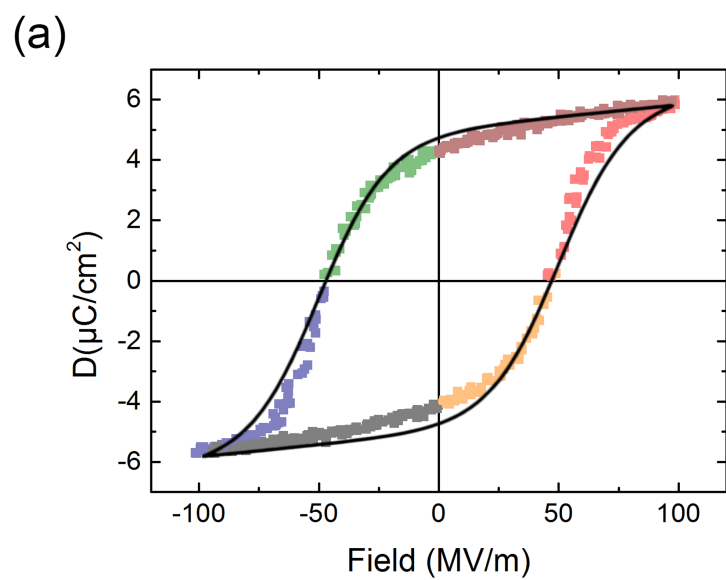


(c)









Supplementary Information

The negative piezoelectric effect of the ferroelectric polymer poly(vinylidene-fluoride)

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1. Supplementary Introduction

The first section of this Supplementary Information contains a detailed description of the dimensional model that is commonly used to explain the negative piezoelectric effect in ferroelectric polymers. Sections 3-5 contain the experimental details about capacitor fabrication and characterization of the microstructure of the P(VDF-TrFE) films by X-ray diffraction measurements, SEM and atomic force microscopy. Subsequently, in sections 6 and 7 the experimental details for the dynamic in-situ X-ray measurements are presented, and the data acquisition and synchronization are discussed. In section 8 we show that clamping effects can be ignored. In section 9 we present the extraction of piezoelectric coefficients from the strain data. The empirical model that has been previously used to quantitatively describe the polarization as a function of electric field in ferroelectric capacitors is discussed. To take into account that the sign of the strain depends on the relative orientation of electric field and polarization we introduce a parity function, \hat{p} . The consequences are discussed. The strain is normalized to zero at zero electric field. The justification is presented. Section 10 contains an overview of all measurements, where the frequency and amplitude of the driving signal were varied systematically. The data sets and fits, as well as the extracted parameters, are presented. For completeness, X-ray measurements at low electric field are included. In section 11 we analyze reported strain measurements on ferroelectric β -PVDF films. In section 12 we discuss the relation between piezoelectric coefficients and ferroelectric properties as extracted for thick films, where we varied the microstructure by varying the annealing temperature.

2. Dimensional model

Various mechanisms have been proposed to explain the negative piezoelectric effect in PVDF and its copolymers. A commonly used explanation is the “dimensional effect”, which assumes that the dipoles are rigid and retain their fixed moment and orientation during mechanical deformation.^[1,2,3] PVDF is a semi-crystalline polymer with a crystallinity of about 50%. Piezoelectricity is then assumed to be due to a change in volume of the amorphous part of the sample. The dimensional model basically describes the displacement of surface electrodes in the fields of fixed dipole moments of polar crystals, as schematically depicted in Fig. S1.

The magnitude of the piezoelectric effect can be estimated as follows. We apply an electric field, E , perpendicular to a thin P(VDF-TrFE) film sandwiched between two electrodes. The electric field is parallel to the poling direction. The relative change in film thickness, the longitudinal strain S_{33} , is then given by:

$$S_{33} = d_{33}E \quad (\text{S1})$$

where d_{33} is the linear, longitudinal piezoelectric coefficient. The film exhibits a spontaneous polarization P_s , equal to the macroscopic dipole moment, μ , over the sample volume, V .

Conversely, the piezoelectric coefficient is the change in polarization with applied uniaxial stress, σ . At zero applied electric field:

$$d_{33} = \left. \frac{\partial P_s}{\partial \sigma} \right|_{E=0} = \frac{\partial \left(\frac{\mu}{V} \right)}{\partial \sigma} = P_r \left(\frac{\partial \ln \mu}{\partial \sigma} - \frac{\partial \ln V}{\partial \sigma} \right) = P_r \left(\frac{\partial \ln \mu}{\partial \sigma} - \frac{1}{Y} \right) \approx -\frac{P_r}{Y} \quad (\text{S2})$$

where Y is the Young's modulus, which is the reciprocal of the compliance, $\partial \ln V / \partial \sigma$. In the dimensional model the crystalline parts are assumed to be independent from the amorphous matrix. The dipoles are rigid and the first term on the left hand side of Eq.[S2] can be disregarded. Taking a typical value for the remanent polarization of 70 mC/m² and a Young's modulus of 2×10^9 N/m² [3,4] then yields an estimated value for d_{33} of -35 pC/N, or -35 pm/V. This value is comparable to the experimental value of -30 pm/V.^[5] Reports on detailed analysis of experimental piezoelectric coefficients estimated that the contribution of the dimensional effect is 75% or more. The additional minor contributions have been ascribed to a variety of effects such as vibrations of the molecular dipoles^[6] and space charges.

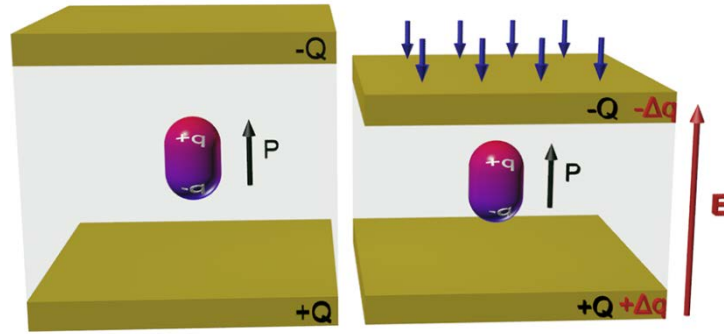


Figure S1. Dimensional effect. We consider a capacitor consisting of a fixed dipole embedded in a linear dielectric. The electric field of the dipole induces surface charge $-Q$ at the top electrode and $+Q$ at the bottom electrode. We apply compressive stress, σ , which decreases the thickness. The dipole is assumed to be rigid and the deformation is accommodated by the amorphous matrix. The concomitant increase of the capacitance dictates that the charges on the electrodes are adjusted by $\pm \Delta Q$. Temporarily there is current flowing through the circuit. The additional charge corresponds to an electric field in the direction of the polarization. The contraction in tandem with the relative orientation of the polarization and the electric field correspond to a negative piezoelectric coefficient.

3. Capacitor fabrication and characterization

The random copolymer of P(VDF-TrFE) (65/35) was purchased from Solvay. Thin films were spincoated on single crystalline quartz substrates from a 4 wt% solution in 2-butanone, typically at 2000 rpm. The layer thickness as measured with a DEKTAK surface profilometer

amounted to 450 nm. The layers were then annealed for 2 hours in vacuum at 140 °C to enhance the ferroelectric properties. As a bottom electrode we used Pd, with 2 nm Cr as an adhesion layer. Au cannot be used due to interference of its X-ray diffraction pattern with that of P(VDF-TrFE). To allow *in-situ* grazing incidence X-ray diffraction measurements (GI-XRD), large device areas of 1 cm² were fabricated. As a top electrode we used a thin film of the amorphous conducting polymer PEDOT:PSS, a water-based suspension of poly(3,4-ethylenedioxythiophene) stabilized with poly(4-styrenesulphonic acid) (AGFA ICP 1020 (Agfa-Gevaert). To prevent dewetting a few drops of the nonionic Zonyl FSO-100 (DuPont) fluoro-surfactant were added to the solution. The PEDOT:PSS layer thickness amounted to 100 nm and the conductivity amounted to 300 S/cm. Finally, the redundant PEDOT:PSS was removed by reactive ion etching using a shadow mask.

Electric displacement loops versus electric field for the capacitors were measured using a Sawyer-Tower circuit, consisting of a Tektronix AFG3102 function generator, a LeCroy waveRunner 204Xi 2GHz oscilloscope and a Krohn-Hite 7600 wide-band amplifier. The capacitors were measured with a continuous triangular wave signal, with a frequency between 1 Hz and 100 Hz, using a reference capacitor of 1 μ F.

4. Crystal structure of P(VDF-TrFE)

Grazing incidence X-ray diffraction (GI-XRD), was used to study the crystal structure of P(VDF-TrFE). The homopolymer PVDF tends to crystallize in the thermodynamically stable α structure. This polymorph is paraelectric. The presence of the TrFE monomers in the random copolymer P(VDF-TrFE) destabilizes the α structure. Instead, the copolymers crystallize in a structure resembling the ferroelectric β -phase of PVDF. Thin P(VDF-TrFE) films appear to contain two phases after deposition. These phases resemble the α - and β -forms of the homopolymer PVDF. After annealing at 140°C, where a non-ferroelectric high temperature (HT) phase is formed, and subsequent cooling to room temperature, only the β -type phase remains. Two modifications of this phase have been described in literature, called the ‘cooled phase’ (CL) and the “low temperature phase” (LT), both found in bulk material.

Table S1. Crystallographic data of several PVDF and P(VDF-TrFE) phases. *The data are compiled from “Ferroelectric Polymers, chemistry, physics and applications” edited by Hari Singh Nalwa.^[7]*

Phase	Conditions	Structure	Chain	A	b	c	β
HT	P(VDF-TrFE) 55/45, 80°C	orthorhombic	Random	9.75 Å	5.63 Å	4.60 Å	---
LT	P(VDF-TrFE) 55/45	monoclinic	all T	9.12 Å	5.25 Å	2.55 Å	93°
CL	P(VDF-TrFE) 55/45	monoclinic	mostly T	9.16 Å	5.43 Å	2.53 Å	93°
	P(VDF-TrFE) 37/63			9.37 Å	5.52 Å	2.53 Å	93°
I / β	PVDF	Cm2m (38)	all T	8.58 Å	4.91 Å	2.56 Å	---
II / α	PVDF	P2 ₁ /c (14)	TGT-G	4.96 Å	9.64 Å	4.62 Å	90°

Pure PTrFE is supposed to have a structure very similar to the P(VDF-TrFE) CL phase. This phase consists of small domains of all trans chains bordered by single gauche bonds. These gauche bonds slightly change the unit cell parameters, compared to the LT phase. The chains will be wider and shorter, resulting in an increase in a- and b- axes and a decrease in c axis. Furthermore, the LT phase is pseudohexagonal ($a/b = \sqrt{3}$), resulting in a combined 1.1.0 / 2.0.0 diffraction peak. For the CL phase $a/b < \sqrt{3}$, therefore the 1.1.0 and 2.0.0 peaks do not coincide. These peaks are also wide, caused by the small domain size, typical for the CL phase.

Specular XRD measurements on a series of PTrFE and P(VDF-TrFE) thin films are presented in Fig. S2. After annealing at 140°C only the LT phase is present for all investigated compositions. Only a single diffraction peak of the combined 1.1.0/2.0.0 diffraction is visible. The peak is relatively sharp. The inset shows the peak position as a function of composition. The trendline gives the combined d spacing for samples with 50% VDF or more. In the dynamic *in-situ* measurements we used P(VDF-TrFE) (65/35). This polymer crystallizes in pseudo-hexagonal LT phase with unit cell parameters of $a = 9.04 \text{ \AA}$, $b = 5.22 \text{ \AA}$, $c = 2.55 \text{ \AA}$ and $\beta = 93^\circ$.

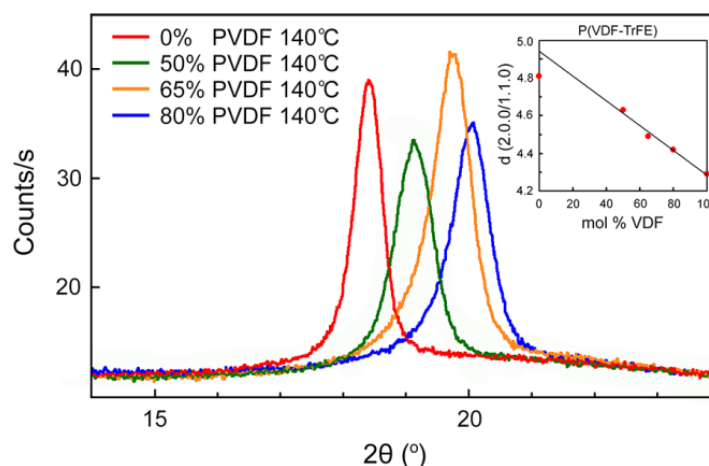


Figure S2. Specular XRD measurements of PTrFE and P(VDF-TrFE). The (110)/(200) diffraction peak of P(VDF-TrFE) films is presented for different compositions. The inset shows the peak position as a function of composition. The trend line gives the combined d spacing for samples with 50% VDF or more.

5. Microstructure of PVDF and P(VDF-TrFE)

PVDF and its random copolymers are semi-crystalline with a crystallinity of about 50%. A typical AFM height picture of a PVDF film is shown in Fig. S3a. The microstructure consists of large lamellae with diameters up to several microns. The lamellae are sheets of crystals that grow outward starting from a central nucleation site. The interlamellar space is filled with an amorphous phase. The crystalline and amorphous parts are strongly intertwined. A typical SEM picture of the random copolymer P(VDF-TrFE) is presented in Fig. S3b. The copolymer

crystallizes in small needle like-domains. Details of the packing and folding of the polymer chains are not completely known but, as in PVDF, the amorphous and crystalline phases appear to be intermixed.

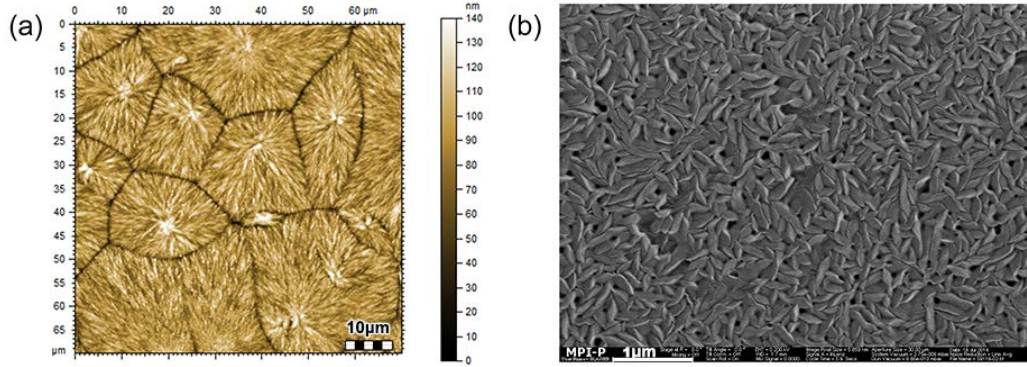


Figure S3. Microstructure of PVDF and P(VDF-TrFE). (a) A typical AFM height image of a PVDF film with a thickness of 117 nm. (b) SEM image of a 500 nm-thick P(VDF-TrFE) film spincoated on a quartz substrate. The scan sizes are indicated by the respective scale bars.

6. Dynamic in-situ X-ray measurements and data acquisition

In-situ grazing incidence X-ray diffraction measurements (GI-XRD) were conducted on the purpose-built, large-area capacitors described in Section 3. Measurements were performed on samples aligned in the high precision 6-circle diffractometer installed at the High Resolution Diffraction Beamline P08 at PETRAIII, Deutsches Elektron Synchrotron (DESY), Hamburg. The 25 keV X-ray beam was focused at the sample position with a compound refractive lens, and the beam size at the sample was set to 50x500 μm by a set of slits. The incidence angle on the sample was set to 0.25°, matching the X-ray footprint to the active area of the device. A Cyberstar scintillation detector was used to align samples in the specular geometry, after which the time-resolved data was measured on a Pilatus 100K area pixel detector placed at 2 m distance to the sample, collecting the out-of-plane scattering between angles of $2\theta = 5.4^\circ$ and $2\theta = 6.5^\circ$ in the specular plane, corresponding to wave vector transfer of 1.19 \AA^{-1} and 1.44 \AA^{-1} , respectively.

A triangular waveform was used to drive the ferroelectric capacitors. The amplitude and the frequency of the triangular driving waveform were varied. The applied AC voltage and the capacitor response were recorded as a function of time using an oscilloscope in a Sawyer-Tower configuration. The circuit consisted of a Tektronix AFG3102 function generator connected to a Krohn-Hite 7600 wide-band amplifier, monitored by a LeCroy waveRunner 204Xi 2GHz oscilloscope. The displacement of the ferroelectric capacitor was determined by monitoring the voltage drop over a large (1 μF) reference linear capacitor in series.

A TTL trigger signal was generated at the (negative-to-positive) zero-crossing of the driving voltage by a Highland P400 delay and pulse generator. The trigger pulse was sent to the

Pilatus 100K, starting an exposure-series of 10000 images of the X-ray scattering signal measured at 100Hz. Each image was integrated for 5.3 ms and the Pilatus delivered a TTL signal mirroring the image integration. This signal was also monitored by the oscilloscope. The oscilloscope output was saved for each exposure series such that the electric displacement, the applied electric field, the trigger pulse and the detector exposure signal were recorded for each scan. An example of recorded data is shown in Fig. S4.

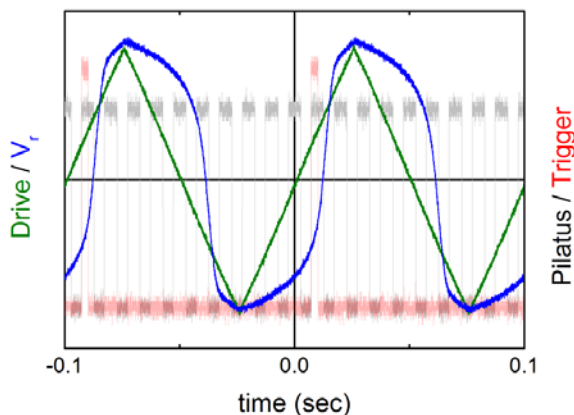


Figure S4. Recorded electrical data. Example of recorded data from the 4 channels of the oscilloscope during measurements of a capacitor driven with a triangular waveform of 120Vpp at 10Hz (green line). The TTL trigger signal (red) is sent at the negative-to-positive zero-crossing of the driving voltage, starting the integration of the first image of the Pilatus 100K (black, each positive plateau is a single image, detector frequency is about 100 Hz). The blue line is the voltage over the reference capacitor.

Two types of X-ray exposure series were measured during the experiment. The frequency of the X-ray exposures were either a multiple of the driving frequency, or the two frequencies were mismatched. In the first case, good statistics were accumulated at given, predefined set of time-delays. In the second case, the X-ray data could be re-binned to any given step-size. The time-resolution of the second type of scans is given by the 5.3 ms integration time of each image.

The specular scattering images recorded by the Pilatus 100K (Fig. S5a) were azimuthally integrated and exposures pertaining to the same time-bin were averaged. An example of the signal after integration and binning is presented in Fig. S5b, showing the dynamics of the coinciding (200) and (110) Bragg peaks throughout the 1Hz cycle of the applied driving waveform. The peak was found around 1.3 \AA^{-1} for all samples, and could be described with a SplitPearsonVII peak fit. A typical fit is shown in Fig. S5c for the data of the bin corresponding to 0.75 s after the zero-crossing of the driving electric field. In this way, the Bragg peak position could be extracted for each bin through peak fits to the averaged data of each time-bin. Attempts to describe the scattering signal as two peaks through constrains of the fit parameters did not systematically improve the fits, and hence the scattering is modeled by a single SplitPearsonVII peak.

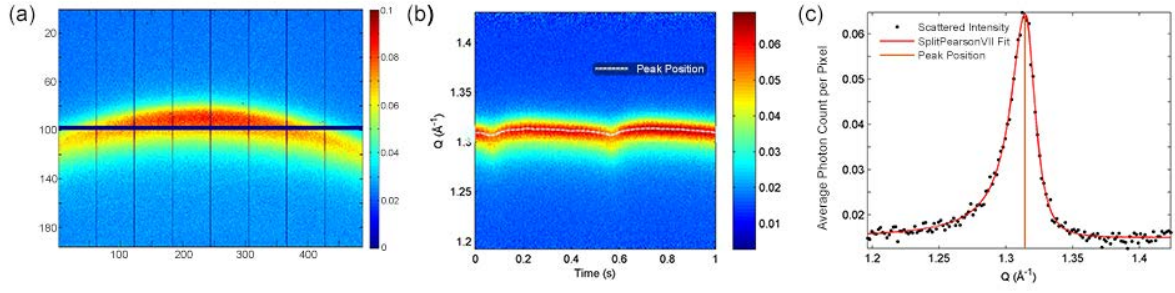


Figure S5. Measured scattering intensity. (a) Raw 2D diffraction data. (b) The azimuthally integrated and averaged data as a function of time in a scan where the capacitor was driven with a 1 Hz triangular waveform. (c) The data recorded at 0.75 s delay, fitted with a SplitPearsonVII peak fit.

7. Data synchronization

The number of measurement points of the scattering vector per period of the driving signal is determined by the ratio of the frequencies of the Pilatus 100K and the triangular driving waveform. With the frequency of the Pilatus 100K detector known, the binned data from the detector can be time-tagged. Subsequently, the time-tagged data are time-shifted to the first exposure of the Pilatus 100K after the trigger pulse, as shown in Fig. S6, which is an enlargement of Fig. S4 in the vicinity of the trigger pulse. This routine unambiguously synchronizes the electrical and X-ray data.

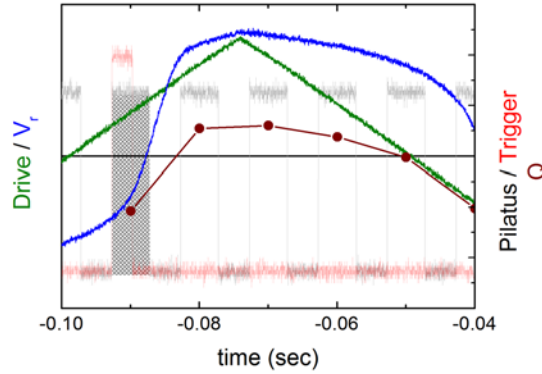


Figure S6. Synchronized data. The averaged, time-tagged X-ray data (brown points) have been time-shifted so that the first point coincides with the first exposure after the trigger signal.

We note that the Pilatus 100K detector collects data throughout each exposure window. Each point of the binned data contains the integrated signal from the sample during the time when the detector-gate signal is positive (grey box in Fig. S6). Therefore each point has been placed in the middle of the exposure window. This averaging works best when the exposure window is small in respect to the temporal change of the electric displacement of the capacitor. Hence

the Pilatus 100K recording frequency was always at least an order of magnitude higher than that of the driving signal.

To increase the measured points per period and to allow higher driving frequencies, we recorded a series of measurements where the driving frequency and the read-out frequency of the Pilatus 100K detector were mismatched. By mismatching the frequencies such that a non-integer number of detector images are acquired every period of the drive frequency, the acquired images can be rebinned according to the individual timing of each image. With accurate time information, this binning results in a significantly better time resolution, limited by the choice of exposure time. The measured GI-XRD images were rebinned according to the relative timing between the middle of the exposure window for the individual images and the driving frequency. The mismatched data presented here were rebinned to 50. An example of such data is presented in Fig. S7.

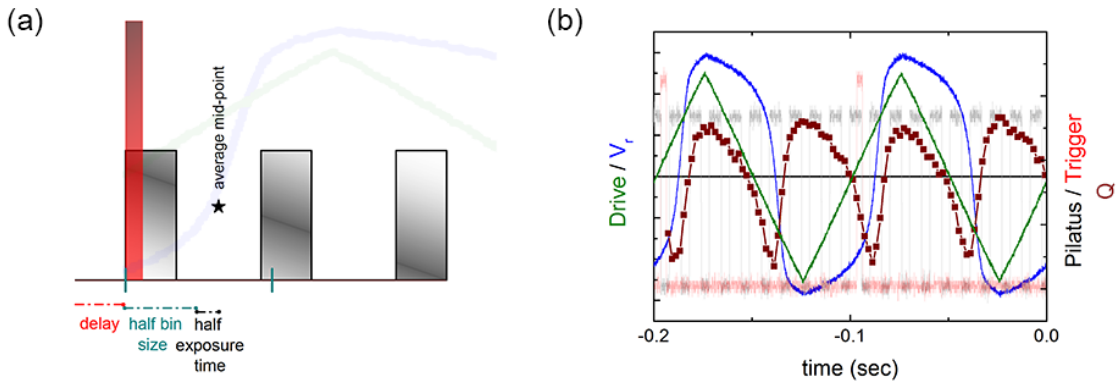


Figure S7. Data from mismatched frequencies. (a) Definition of the average midpoint (in time) of the exposures going into the first time-bin, represented by the black star. The data of the time-bin are given by the average of all exposures started at time-points within the time bin (here, between the dark cyan lines). This means that data from both the first and second exposure in the illustrated example (grey rectangles) will go into the first time-bin. On average, the midpoint (in time) of the exposures going into the first time-bin will be given by: the delay of the exposure trigger with respect to time-zero of the oscilloscope (red dashed line) + half the bin size (dark cyan dashed line) + half the exposure time (black dashed line). (b) Synchronized detector data using a driving signal of 10Hz and an exposure frequency of $\sim 98.04\text{Hz}$. The bin number was chosen to be 50.

The GI-XRD data as well as the electric displacement data were interpolated to the same number of points within one period. We calculated the lattice constant as $l=2\pi/Q$ and plotted the strain as the relative change in lattice constant, $\Delta l/l_0$, where l_0 is the value at zero electric field. The field was calculated from the applied voltage and the layer thickness. The displacement follows from the measured capacitor response. The relative change in lattice constant could be plotted as a function of the driving electric field and measured displacement.

8. Clamping and capacitor layout considerations

The lateral dimensions of a ferroelectric thin film can be constrained by the substrate. In the case of total clamping, the in-plane strain induced by an electric field across the capacitor should be zero; there is no change in the lateral dimensions of the film when an electric field is applied. As a result, in a clamped film the measured piezoelectric coefficient is reduced in respect to the bulk. The effective longitudinal piezoelectric coefficient is:

$$d_{33}^{eff} = d_{33} - \frac{2d_{31}s_{13}^f}{s_{11}^f + s_{12}^f} + \frac{2d_{31}s_{13}^s}{s_{11}^s + s_{12}^s} \quad (S3)$$

where d_{33} and d_{31} are the longitudinal and transverse piezoelectric coefficients of the bulk material and s_{ij}^f and s_{ij}^s are the respective elastic compliances of the film and the substrate, at constant electric field.^[8] Since d_{31} is positive for P(VDF-TrFE), s_{12} , and s_{13} are negative, and s_{11} is positive and larger than s_{12} ,^[9] d_{33}^{eff} can give an underestimation of the real d_{33} .

The third term in Eq.[S3], originating from the elastic deformation and bending of the substrate, can be ignored. In our capacitors the substrate is much larger than the area where the field is applied and, furthermore, the single-crystal quartz used here is rigid.

When the elastic compliance of the film matches the one of the substrate, the deformation of the substrate exactly compensates the clamping effect. The total thickness change of the film/substrate couple is equal to the thickness change of the film without constraint; hence the effective piezoelectric coefficient is the same as in bulk. In our capacitors PEDOT:PSS has a similar compliance to P(VDF-TrFE) of approximately 2GPa,^[3,4] hence we can ignore the clamping effect from the PEDOT:PSS top electrode.

We note that clamping is most relevant in converse piezoelectric measurements by *e.g.* interferometry, where the change in thickness is measured.^[10] A clamped film can expand or contract only in the direction perpendicular to the surface. Here we are calculating the strain from the change in lattice constant.

The value of d_{33}^{eff} for a totally clamped P(VDF-TrFE) film, as calculated by Eq.[S3] using the elastic compliances for P(VDF-TrFE) and a d_{31} of 10pm/V,^[11] is reduced by almost 40%. In contrast, in our measurements the extracted values of the piezoelectric coefficient are in good agreement with those reported in literature for bulk, unclamped P(VDF-TrFE) films, indicating that the effects of clamping are negligible. To verify this, we look closer at the dynamics of the lattice constant change.

If the portion of the crystals in close proximity to the substrate were clamped, the change of their dimensions would be inhibited. That would result in a distribution in the lattice constant, leading to a field-dependent broadening of the measured diffraction peak. We monitor this

broadening by observing the behaviour of the full width at half maximum (FWHM) of the diffraction peak.

Fig. S8a shows the azimuthally integrated and averaged data as a function of time (bin) in a scan where the P(VDF-TrFE) capacitor was driven with a 10 Hz triangular waveform. The peak position and corresponding FWHM as a function of time are presented in Fig. S8b. The FWHM as a function of the applied voltage, after data synchronization, is shown in Fig. S8c. The width is broader only during polarization switching near the coercive voltage. However, the shape and value of the FWHM shows no obvious variations at corresponding voltage values before and after switching. The lattice constant characteristics, as it can be seen in Fig. S8d also remain symmetric. This behaviour supports the claim that our thin-films are not severely clamped by the substrate, as expected for the low compliance P(VDF-TrFE) films and suggested by the value of the measured piezoelectric coefficient.

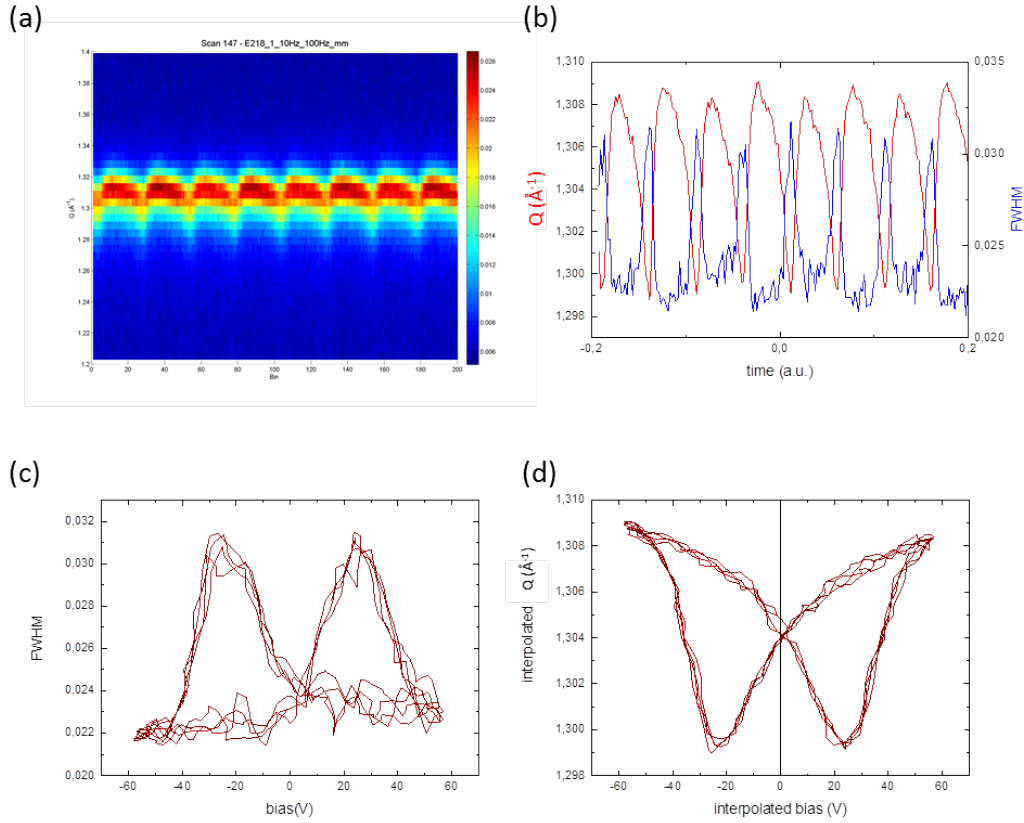


Figure S8. Measured Full Width at Half Maximum. (a) The azimuthally integrated and averaged data as a function of bin in a scan where the capacitor was driven with a 10 Hz triangular waveform. (b) The extracted wave vector and FWHM as a function of time. Plots of (c) FWHM and (d) wave vector as a function of the applied voltage, after data synchronization.

We note that the portion of the film near the edge of the capacitor's electrodes can also be constrained by the redundant ferroelectric material surrounding the active area of the

capacitor, as previously observed in inorganic ferroelectric capacitors.^[12] P(VDF-TrFE), however, has a much lower elastic compliance (2GPa) as compared to PZT (120GPa).^[13] Nevertheless, to avoid any potential constrain effects from the redundant P(VDF-TrFE), the X-ray beam was always focused near the center of the capacitor.

9. Parameter extraction

9.1 Modeling ferroelectric D-E hysteresis loops

We use an empirical model to describe the electric displacement in ferroelectric capacitors. The model is based on a reported analytical description for the saturated and unsaturated polarization as a function of electric field.^[14,15] This methodology has been used to quantitatively describe the charge transport in organic ferroelectric field-effect transistors.^[16] Here we focus on the saturated outer loops. The displacement, D , is the sum of the induced, P_i , and spontaneous, P_s , polarization:

$$D = P_i + P_s = \varepsilon_r \varepsilon_0 E \dot{p} + P_s \quad (\text{S4})$$

where ε_r and ε_0 are the relative and vacuum permittivity and E the electric field over the ferroelectric layer. \dot{p} is a parity function to take into account the relative orientation of electric field and spontaneous polarization. The spontaneous polarization is given by:

$$P_s^+(E, E_{max}) = P_{max} \tanh\left(\frac{E-E_c}{\delta}\right) + \frac{P_{max}}{2} \left(\tanh\left(\frac{E_{max}+E_c}{\delta}\right) - \tanh\left(\frac{E_{max}-E_c}{\delta}\right) \right) \quad (\text{S5})$$

$$P_s^-(E, E_{max}) = P_{max} \tanh\left(\frac{E+E_c}{\delta}\right) - \frac{P_{max}}{2} \left(\tanh\left(\frac{E_{max}+E_c}{\delta}\right) - \tanh\left(\frac{E_{max}-E_c}{\delta}\right) \right) \quad (\text{S6})$$

where P_s^- and P_s^+ correspond to the two composing parts of the hysteresis loop, as seen in Fig. S9. E_{max} is the maximum applied electric field, while P_{max} (maximum polarization), P_r (remanent polarization) and E_c (coercive field) are used as fit parameters. When the maximum field gets much larger than the coercive field the ferroelectric polarization saturates. δ is given by:

$$\delta = 2E_c \left(\ln \left(\frac{1 + \frac{P_r}{P_{max}}}{1 - \frac{P_r}{P_{max}}} \right) \right)^{-1} \quad (\text{S7})$$

The dielectric displacement loops are fitted by adding the induced polarization to the appropriate ferroelectric polarization, *cf.* Eq.[S4].

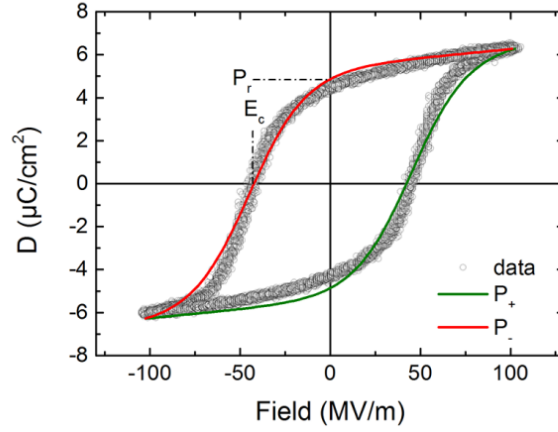


Figure S9. Modeling the ferroelectric D-E hysteresis loop. The measured displacement versus applied electric field for a ferroelectric P(VDF-TrFE) capacitor is presented as the black points. The solid lines are fits to the experimental data according to Eq.[S4-S7].

9.2 Parity function

Due to the fact that the sign of the strain depends on the relative orientation of the applied electric field and the displacement, we include in the quantitative analysis a parity function, \dot{p} . This function varies between -1 and +1, depending on the relative signs of the displacement and field. The parity function can be the delta function as $\text{sign}(E \cdot D)$. However, to describe the gradual change in displacement around the coercive field we included a hyperbolic tangent, $\dot{p} = \text{sign}(E \cdot D) \tanh(|D|)$. As shown in Fig. S10, this extra term changes the rate of the transition from contraction to expansion (and vice-versa) around the coercive field, improving the fit quality. We note that a parity function is not needed to describe the electrostrictive term of the strain, which varies quadratically with displacement, irrespective of the field orientation.

9.3 Normalization of strain

We have calculated the strain from the X-ray data as the relative change in the lattice constant, $\Delta l/l_0$, where l_0 is the lattice constant at zero field. In this representation, the data cross the origin of the strain-field (S - E) plot. The strain is zero at zero electric field. In our phenomenological model the strain is calculated as the sum of a field-dependent and a displacement-dependent term. In the ferroelectric capacitors the remanent displacement at zero electric field leads to a non-zero strain. Hence, a normalization constant c has been included in the model to account for this residual strain. The constant c merely shifts the data to the origin of the strain-field plot and corresponds to $Q_{33}P_r^2$, as further discussed in section S11 below.

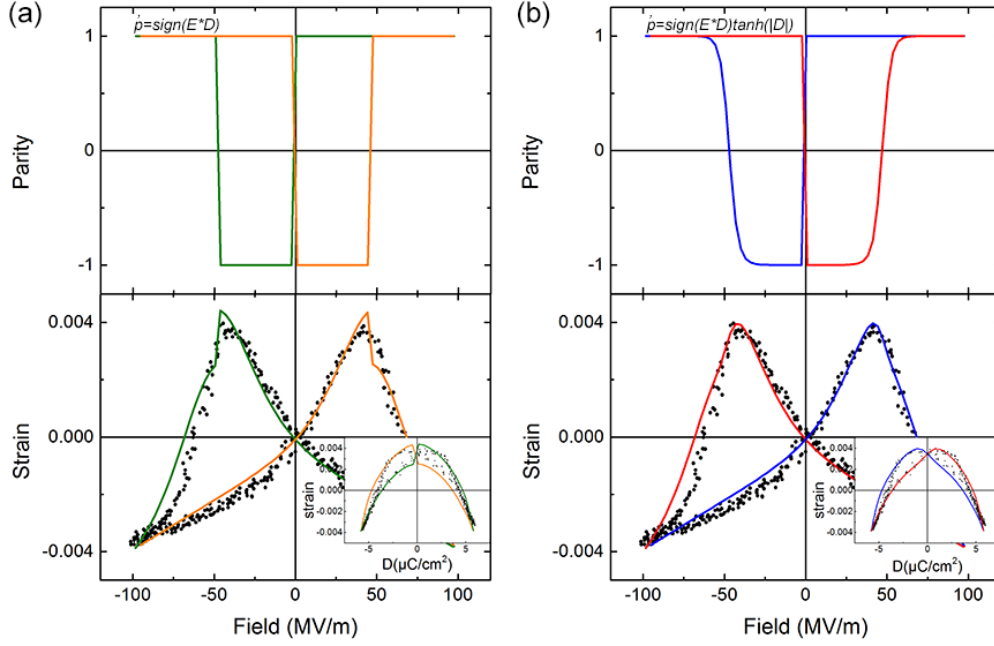


Figure S10. Parity function. Example of (a) square and (b) gradual parity function for a $P(\text{VDF-TrFE})$ capacitor, with the corresponding fits of the S-E characteristics shown. The insets show the fits for the S-D representation of the data.

10. Data series of $P(\text{VDF-TrFE})$

We measured the out-of-plane lattice constant and electric displacement while driving the capacitor with a triangular waveform. The frequency and amplitude of the driving signal were varied systematically. The full datasets and fits, as well as the extracted parameters, are presented in the following sections.

10.1 Amplitude series

The capacitors were driven with a triangular waveform with a frequency of 1 Hz. The amplitude was varied between 20 V and 60 V. The detector frequency was set at 50 Hz. Table S2 shows the strain as a function of electric field and displacement for different amplitudes. The data are represented by the points and the fits are the solid red lines. The extracted parameter d_{33} is indicated.

10.2 Frequency series

The capacitors were driven with a triangular waveform with an amplitude of 60 V. The frequency was varied between 1 Hz and 100 Hz. Table S3 shows the strain as a function of electric field and displacement for different frequency of the driving signal. The detector frequency is indicated. An “m” indicates data acquired from mismatched driving and detector frequencies. The data are represented by the points and the fits are the solid red lines. The extracted parameter d_{33} is indicated.

Table S2. Amplitude series. The strain as a function of electric field and displacement for *P*(VDF-TrFE) capacitors driven with a 1 Hz triangular waveform of different amplitudes. The data are represented by the points and the fits are the solid red lines. The extracted parameter d_{33} is indicated. The relative error of the total d_{33} , calculated by the propagation of uncertainty of the fit parameters E_c , P_r , $d_{coupling}$ and Q_{33} , is less than 3%.

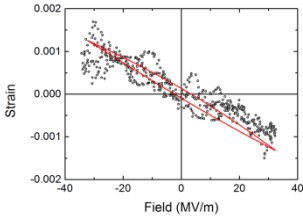
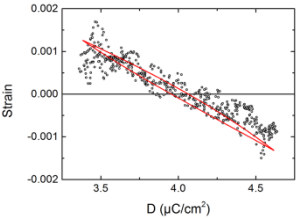
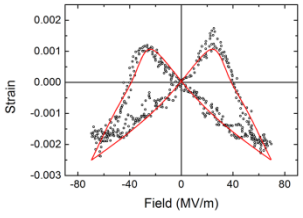
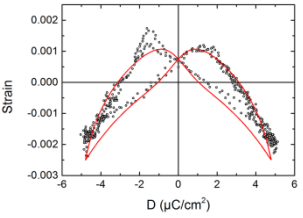
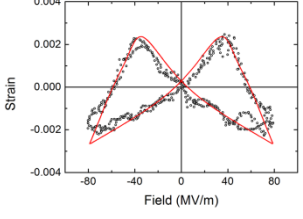
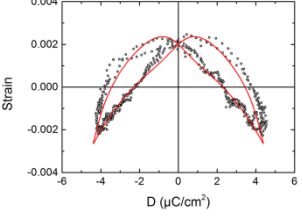
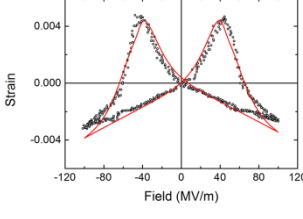
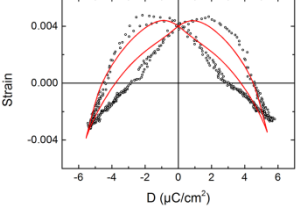
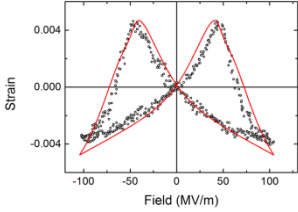
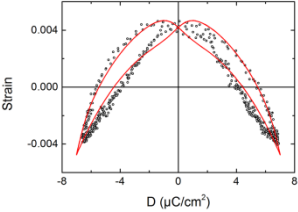
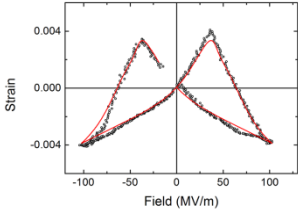
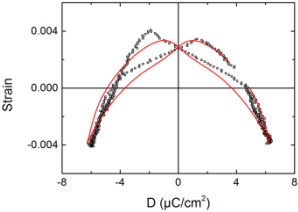
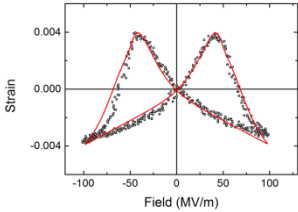
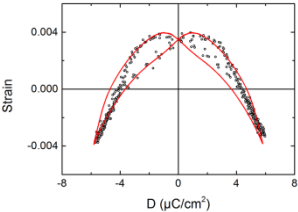
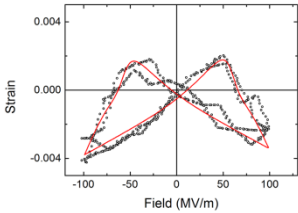
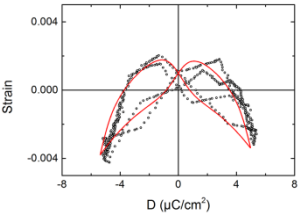
Amplitude	<i>S-E</i>	<i>S-D</i>	d_{33} (pm/V)
20 V			-29.5
40 V			-26.8
50 V			-30.2
60 V			-33.6

Table S3. Frequency series. The strain as a function of electric field and displacement for *P*(VDF-TrFE) capacitors driven with a 120 Vpp triangular waveform of different frequencies. The detector frequency is given in brackets. “m” indicates data acquired from mismatched driving and detector frequencies. The data are represented by the points and the fits are the solid red lines. The extracted parameter d_{33} is indicated.

Frequency	<i>S-E</i>	<i>S-D</i>	d_{33} (pm/V)
1 Hz (100Hz)			-32.7
5 Hz (100Hz)			-29.6
10 Hz (m 98.04Hz)			-32.5
100 Hz (m 98.04Hz)			-29.9

10.3 Determination of d_{33} at low electric field

We corroborate the value of d_{33} , as extracted in our analysis, by dynamic *in-situ* XRD measurements at low electric field. As shown in Fig. S11, the strain is proportional to the electric field and for the proportionality coefficient, d_{33} , a value of -30 pm/V is extracted.

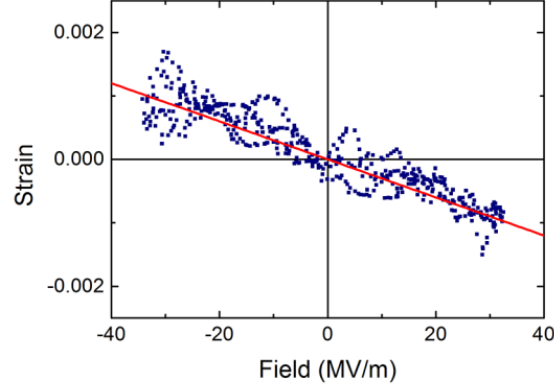


Figure S11. Low-field strain. Strain, extracted as the relative change in out-of-plane lattice constant, versus electric field for P(VDF-TrFE) capacitors. The strain is measured at fields below the coercive field.

11. Modeling of reported strain measurements on β -PVDF

In a seminal paper Furakawa and Seo have shown that the origin of piezoelectricity in PVDF and their copolymers with TrFE is electrostriction.^[17] They measured displacement and strain of uniaxially drawn β -PVDF as a function of electric field. They show that the strain far from the coercive field can be described by the linearized electrostriction equation:

$$S_{33} = Q_{33}D^2 = 2Q_{33}\epsilon_r\epsilon_0P_sE + Q_{33}P_s^2 + Q_{33}\epsilon_r^2\epsilon_0^2E^2 \quad (S8)$$

A good fit for strain data far from the coercive field was obtained. A value for the electrostrictive coefficient, Q_{33} , of $-2.4 \text{ m}^4/\text{C}^2$ was reported. The piezoelectric coefficient, d_{33} , was then calculated as:

$$d_{33} = 2Q_{33}\epsilon_r\epsilon_0P_r \quad (S9)$$

as the experimental measurements were performed at low electric fields, where the spontaneous polarization is constant and equal to the remanent polarization. A value of -33 pm/V was derived in fair agreement with their experimentally determined value of 26 pm/V . Hence the origin of piezoelectricity in PVDF-based ferroelectric polymers is electrostriction biased by the spontaneous polarization.

The reported values for the strain are replotted in Fig. S12 as a function of the displacement. The strain has been normalized to zero at zero electric field. Looking at Eq.[S8] the experimental data have been shifted over $Q_{33}P_r^2$, as the spontaneous polarization at zero electric field is equal to the remanent polarization.

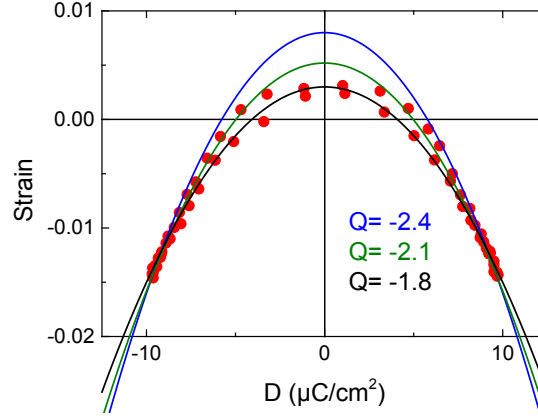


Figure S12. Strain and displacement of uniaxially drawn PVDF. Strain as a function of displacement, D , of uniaxially drawn PVDF. The data are reproduced from Ref. [17]. The black, green and blue lines are calculated using the electrostriction equation Eq.[S8], with values of the electrostrictive coefficient, Q_{33} , of -1.8 , -2.1 and $-2.4 \text{ m}^4/\text{C}^2$ respectively. The green line is used in the reported plots of Ref.[17]. The blue line is calculated using the value for Q_{33} of $-2.4 \text{ m}^4/\text{C}^2$ as reported in Table I of Ref.[17].

We fit the data by taking only electrostriction into account, Eq.[S8]. The fit is presented as the black line. The strain at $D=0$ is equal to $Q_{33}P_r^2$. We obtain for the remanent polarization a value of $4.1 \text{ } \mu\text{C}/\text{cm}^2$, in fair agreement with the experimental value of $5.6 \text{ } \mu\text{C}/\text{cm}^2$. A value for the electrostrictive coefficient, Q_{33} , of $-1.8 \text{ m}^4/\text{C}^2$ was obtained. Using a dielectric constant of 10, we then calculate a value for the piezoelectric coefficient of approximately $-14 \text{ pm}/\text{V}$, lower than the experimental value of $-26 \text{ pm}/\text{V}$.

In Ref. [17] a different fit to the experimental data is used, as represented by the green line in Fig. S12, which corresponds to an electrostrictive coefficient, Q_{33} , of $-2.1 \text{ m}^4/\text{C}^2$. Maybe a better fit is obtained at high displacement, but the remanent strain at zero displacement is now unrealistically large. Finally, we note that Table I in Ref.[17] reports $-2.4 \text{ m}^4/\text{C}^2$ as the extracted value for Q_{33} . The corresponding calculated strain is presented by the blue line. It clearly deviates from the experimental data. Overall, as it can be seen from Fig. S12, the strain does not unambiguously depend on the value of the displacement; there is hysteresis. Obviously, this hysteresis cannot be described by the electrostriction equation, Eq.[S8].

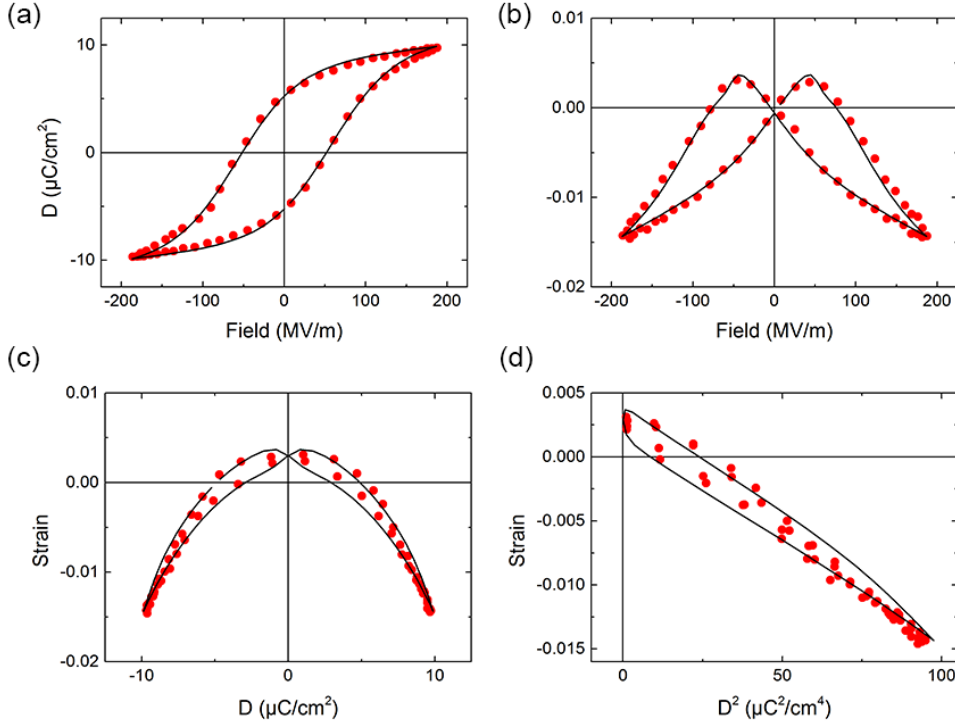


Figure S13. Strain and displacement of uniaxially drawn PVDF. (a,b,c,d) D - E , S - E , S - D and S - D^2 representations. The red dots represent the experimental data taken from Ref. [17]. The solid black lines are fits according to Eq.[S10]. The extracted fit constants are presented in Table S4.

The hysteresis implies that there must be an additional contribution to the lattice strain. Hence as a next step to arrive at a fully analytical description of the complete strain versus electric field measurements, we added the additional term, $d_{coupling}E\dot{p}$. $d_{coupling}$ is a phenomenological fit constant and E is the applied electric field. \dot{p} is the parity function, with values of -1 or +1, to take into account the relative orientation of electric field and spontaneous polarization, which are independent for a poled piezoelectric material. The lattice strain now reads:

$$S_{33} = d_{coupling}E\dot{p} + Q_{33}D^2 = (d_{coupling} + 2Q_{33}\epsilon_r\epsilon_0P_s)E\dot{p} + Q_{33}P_s^2 + Q_{33}\epsilon_r^2\epsilon_0^2E^2 \quad (S10)$$

The strain was fitted to the reported experimental data. The replotted data and fits are presented in Fig. S13. The red dots are replotted experimental data. The fully drawn curves are simultaneously fitted to the data according to Eq.[S10]. An excellent agreement is obtained. The full reported data set can unambiguously and quantitatively be interpreted, including all the data at all electric fields and including the hysteresis. The values extracted for the extracted piezoelectric and electrostrictive parameters are presented in Table S4. The value of the piezoelectric coefficient of -37 pm/V is in fair agreement with the experimentally reported value of -26 pm/V. Furthermore, the values extracted from measurements on bulk thin films are comparable to those derived from the dynamic, in-situ XRD measurements on

P(VDF-TrFE). The similar values once again indicate that piezoelectricity in PVDF and its copolymers is dominated by the change in the lattice constant.

Table S4. Extracted piezoelectric coefficients of uniaxially drawn PVDF

Material	E_c (MV/m)	P_r ($\mu\text{C}/\text{cm}^2$)	Q_{33} (m^4/C^2)	d_{coupling} (pm/V)	$2Q\epsilon_0\epsilon_r P_r$ (pm/V)	d_{33} (pm/V)
β -PVDF	58	5.5	-1.3	-25	-12.7	-37.7

To illustrate that the strain is still dominated by electrostriction we present in Fig. S14 the experimental values of the strain and the electrostrictive contribution as a function of electric field. The experimental strain is taken from Ref.[17], and the electrostrictive contribution is taken as $Q_{33}D^2$. The strain is clearly dominated by electrostriction. The difference is due to the additional term, $d_{\text{coupling}}E\dot{p}$, which becomes increasingly important with increasing electric field and introduces the experimentally observed hysteresis.

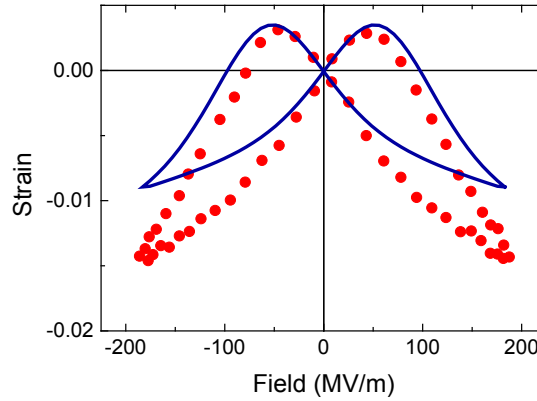


Figure S14. Electrostrictive contribution to the strain. Strain of uniaxially drawn PVDF as a function of electric field, E . The experimental data are taken from Ref. [17] and presented by the red points. The electrostrictive contribution to the strain, $Q_{33}D^2$, is presented by the blue line. The difference is due to the additional term $d_{\text{coupling}}E\dot{p}$.

12. Variation of extracted piezoelectric coefficients with microstructure

To support the modeling we fabricated thick films of P(VDF-TrFE) (65/35). Films were spincoated from a 250 mg/ml solution of P(VDF-TrFE) in methyl-ethyl-ketone at 500 rpm and dried overnight under vacuum. In order to obtain smooth films, the relative humidity during spincoating was kept below 3% by flushing with nitrogen.^[18] The film thickness amounted to about 30 μm . The films were annealed in vacuum for two hours at different temperatures, up to a maximum of 140 $^{\circ}\text{C}$ and subsequently slowly cooled down. The films

annealed up to 100 °C could be easily peeled off the glass substrate by washing in deionized water with a little detergent. Films annealed at higher temperatures adhered to the substrates. To facilitate peeling off, the P(VDF-TrFE) films were spincoated on glass covered with an interlayer of PEDOT:PSS. The films were contacted on both sides with 100 nm thick circular evaporated gold contacts with an area of 0.78 cm².

The films were characterized by differential scanning calorimetry measurements (DSC) and specular wide angle X-ray diffraction measurements (XRD), using a Philips PW1820 diffractometer with Cu radiation. DSC thermograms were recorded up on a Mettler-Toledo 822/400 DSC with a modular measurement unit, using a heating rate of 10 K/min up to 200 °C. The displacement as a function of electric field was measured using a Radiant precision multiferroic test system (Radiant Technologies, Inc.). The strain as a function of electric field was measured simultaneously with the displacement, using a MTI 2100 photonic sensor interfaced with the Radiant tester.

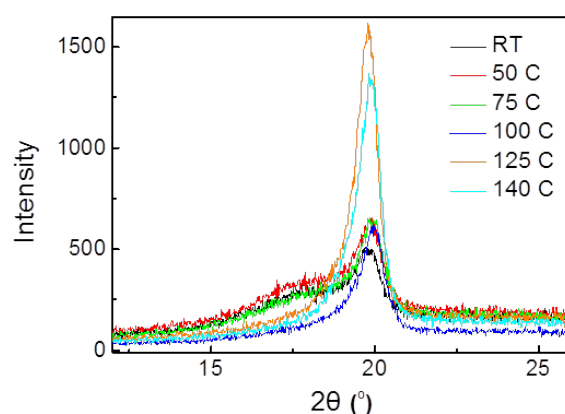


Figure S15. Specular wide angle X-ray diffractograms of P(VDF-TrFE) thick films. *The diffracted intensity is presented as a function of the diffraction angle 2θ . The spincoated films were annealed for 2 hours at the indicated temperature and then slowly cooled down to room temperature.*

The microstructure and composition of P(VDF-TrFE) films cannot be varied indefinitely by annealing. Films prepared by spincoating at room temperature are already crystalline. In an attempt to make amorphous films, films were annealed for 2 hours at 200 °C, above the melting temperature, and subsequently quenched in ice water. In an attempt to increase the fraction of the HT phase, films were molten at 200 °C, annealed at 150 °C for 2 hours, above the Curie temperature, and either quenched in ice water or slowly cooled down to room temperature. In all cases, however, the diffractograms showed only the characteristic peak of the ferroelectric LT phase of P(VDF-TrFE).

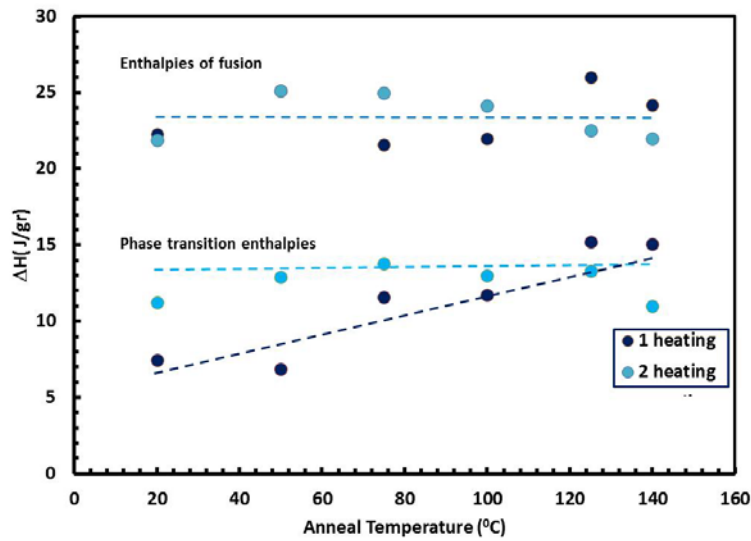


Figure S16. Enthalpies of fusion and phase transition enthalpies for P(VDF-TrFE) (65/35) as a function of anneal temperature. *The values are obtained by integrating the area of the endotherms in the first and second DSC heating diagrams, presented by the black and cyan symbols, respectively.*

The limited change in microstructure is reflected in the DSC measurements. The thermograms show the phase transition between the LT and the HT phase at the Curie temperature of about 100 °C and melting at around 152 °C. The thermograms are similar to previously reported ones. A detailed interpretation is presented in Ref.[19]. The enthalpy of fusion is a measure for the crystallinity of the films. As shown in Fig. S16, the values in the first and second heating are similar and do not vary with annealing temperature, indicating that the crystallinity does not significantly change upon annealing, in good agreement with the X-ray diffraction measurements. The phase transition enthalpy is the energy necessary for the LT to the HT transition at the Curie temperature. The value is a measure of the amount of the ferroelectric LT phase present in the sample. Fig. S16 shows that in the pristine films the amount of LT phase strongly increases with annealing temperature. In good agreement with the X-ray diffraction measurements, annealing of P(VDF-TrFE) films will only slightly increase the crystallinity; the main effect is a transformation from the paraelectric HT phase to the ferroelectric LT phase.

All films were electrically characterized by simultaneous displacement and strain measurements as a function of electric field. The experimental data were fitted according to Eq. [S10]. For all films a good fit is obtained.

The extracted remanent polarization is presented as a function of anneal temperature in Fig. S17. The polarization increases with increasing annealing temperature, in good agreement with the X-ray diffraction measurements that show a comparable increase in content of the ferroelectric LT phase of P(VDF-TrFE).

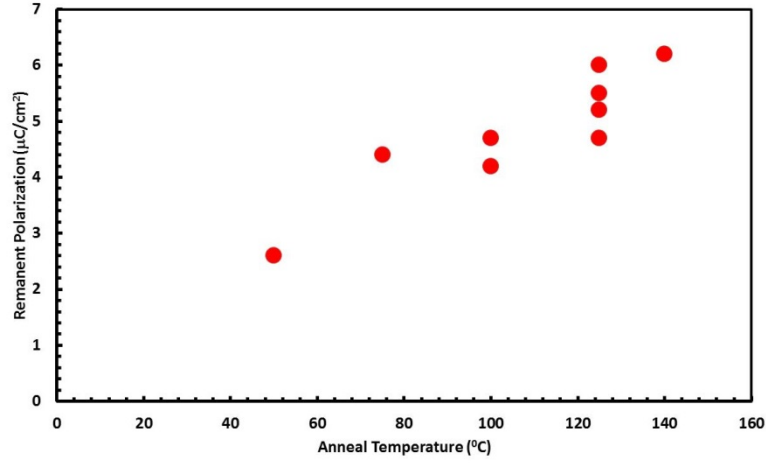


Figure S17. Remanent polarization as a function of annealing temperature. *The remanent polarization was determined from the ferroelectric hysteresis loops of 30 μm thick P(VDF-TrFE) films, annealed at different temperatures.*

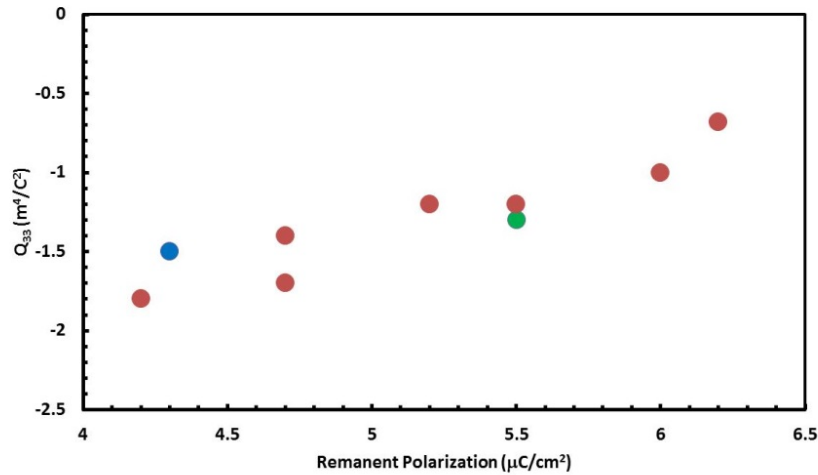


Figure S18. Extracted electrostriction coefficient, Q_{33} , as a function of remanent polarization. *Red data points are extracted from strain measurements on 30 μm thick P(VDF-TrFE) films. The blue data point is extracted from dynamic in-situ GI-XRD measurements on P(VDF-TrFE) 500 nm thin film capacitors. The green data point is extracted from strain measurements on uniaxially drawn β -PVDF as reported in Ref.[17] and reinterpreted as described in section 11 above.*

The extracted values for the electrostrictive coefficient, Q_{33} , are presented as a function of remanent polarization in Fig. S18. The red data points are extracted from the 30 μm thick P(VDF-TrFE) films. The blue data point is extracted from the dynamic in-situ GI-XRD measurements on P(VDF-TrFE) 500 nm thin film capacitors. The green data point is extracted

from strain measurements as reported in Ref.[17], and reinterpreted as described in section 11 above, Table S4. The extracted values show a monotonous dependence on remanent polarization. We note that the electrostrictive coefficient is proportional to the compliance over the dielectric constant.^[20] The Young's modulus, which is the reciprocal of the compliance, has been reported for undrawn P(VDF-TrFE).^[21] The films show so-called mechanical hardening as a result of poling; the Young's modulus gradually increases with increasing remanent polarization.^[21] Hence the change in the electrostriction coefficient with polarization can probably be explained by a change in Young's modulus.

The extracted piezoelectric coefficients, $d_{couplings}$, and d_{33} , are presented as a function of remanent polarization in Fig. S19. Blue symbols represent $d_{couplings}$ and red symbols represent d_{33} . Round symbols are extracted from strain measurements on 30 μm thick P(VDF-TrFE) films. The diamond symbols are extracted from dynamic in-situ GI-XRD measurements on P(VDF-TrFE) 500 nm thin film capacitors and from strain measurements on uniaxially drawn β -PVDF as reported in Ref. [17], and reinterpreted as described in section 11 above.

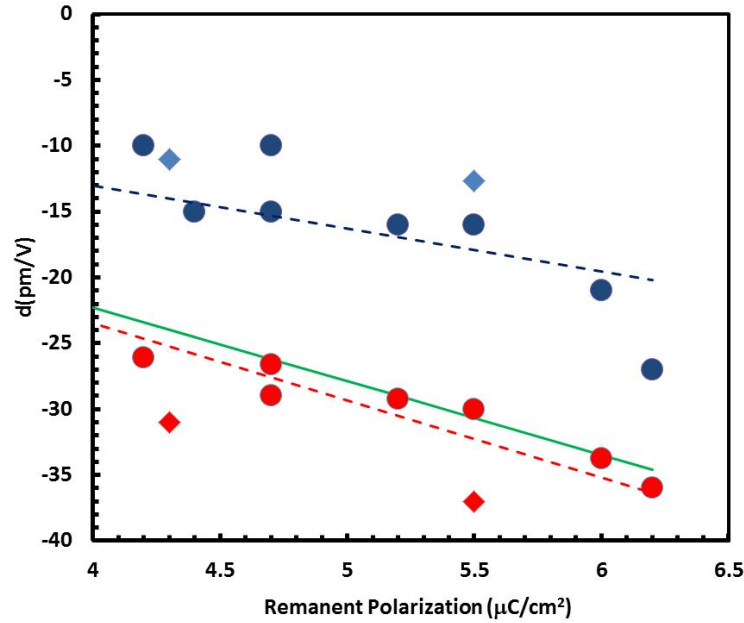


Figure S19. Extracted piezoelectric coefficients, $d_{couplings}$, and d_{33} , as a function of remanent polarization. Blue symbols represent $d_{couplings}$ and red symbols represent d_{33} . Round symbols are extracted from strain measurements on 30 μm thick P(VDF-TrFE) films. The diamond symbols are extracted from dynamic in-situ GI-XRD measurements on P(VDF-TrFE) 500 nm thin film capacitors and from strain measurements on uniaxially drawn PVDF as reported in Ref.[17], and reinterpreted as described in section 11 above. Dashed lines are linear fits through the origin. The green line represents the experimentally measured d_{33} values for undrawn PVDF as a function of remanent polarization, as reported in Ref.[21].

We have interpreted the piezoelectric coefficient, $d_{coupling}$, as being due to an additional electromechanical coupling between the intermixed crystalline lamellae and amorphous regions of the semi-crystalline polymer. The absolute value of $d_{coupling}$ then should increase with the dipole density. Hence a relation with the remanent polarization might be expected. The blue dashed line is a linear fit to the data through the origin. In first order approximation, the experimental data can be well described.

The total longitudinal piezoelectric coefficient, d_{33} , as measured at low electric fields, where the change in spontaneous polarization with electric field can be disregarded, is given by:

$$d_{33} = \left. \frac{dS_{33}}{d(pE)} \right|_{E=0} = d_{coupling} + 2Q_{33}\epsilon_r\epsilon_0 P_r \quad (S11)$$

When $d_{coupling}$ depends linearly on the remanent polarization, then Eq.[S11] shows that the total extracted longitudinal piezoelectric coefficient, d_{33} , should be directly proportional to the remanent polarization. We note that small deviations are expected due to the variation of the electrostrictive coefficient, Q_{33} , with polarization as shown in Fig. S18. The red dashed line is a linear fit of the extracted d_{33} values as a function of remanent polarization. Within the experimentally limited range of remanent polarization an acceptable fit is obtained. More importantly, however, we present in Fig. S19 reported values of the longitudinal piezoelectric coefficient as a function of remanent polarization, as derived for undrawn PVDF.^[21] Reported data are presented by the green line. An excellent agreement is obtained, supporting the analysis used.

Fig. S19 shows that the piezoelectric coefficient contains a contribution from electrostriction and from the additional electromechanical coupling between the intermixed crystalline lamellae and amorphous regions. For the films investigated both contributions are about equal in magnitude and scale with the remanent polarization. We note that the total strain remains dominated by electrostriction via the dominant contribution $Q_{33}P_s^2$, as clearly shown in Fig. S14.

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